

4.5-V TO 20-V INPUT, 3-A OUTPUT SYNCHRONOUS PWM SWITCHER WITH INTEGRATED FET (SWIFT™)

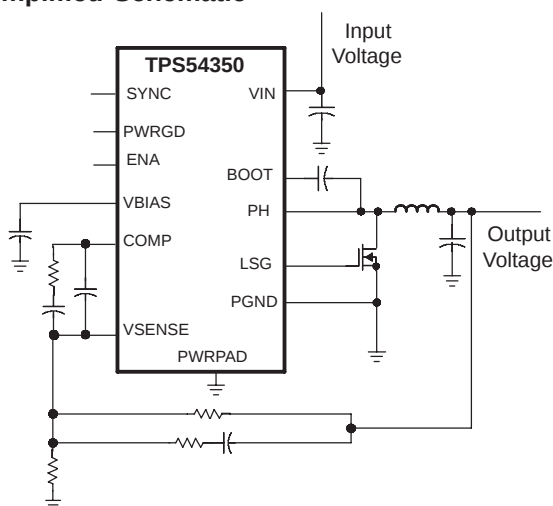
FEATURES

- 100 mΩ, 4.5-A Peak MOSFET Switch for High Efficiency at 3-A Continuous Output Current
- Uses External Lowside MOSFET or Diode
- Output Voltage Adjustable Down to 0.891 V With 1% Accuracy
- Synchronizes to External Clock
- 180° Out of Phase Synchronization
- Wide PWM Frequency – Fixed 250 kHz, 500 kHz or Adjustable 250 kHz to 700 kHz
- Internal Slow Start
- Load Protected by Peak Current Limit and Thermal Shutdown
- Adjustable Undervoltage Lockout
- 16-Pin TSSOP PowerPAD™ Package

APPLICATIONS

- Industrial & Commercial Low Power Systems
- LCD Monitors and TVs
- Computer Peripherals
- Point of Load Regulation for High Performance DSPs, FPGAs, ASICs and Microprocessors

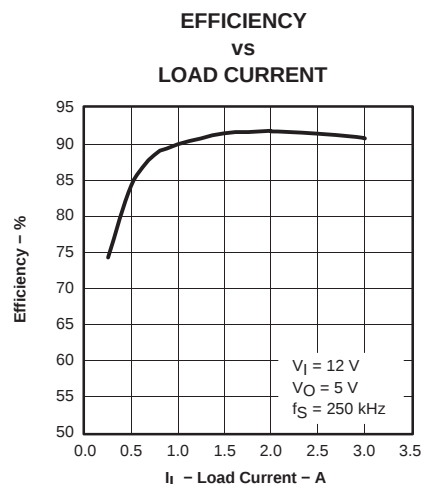
Simplified Schematic



DESCRIPTION

The TPS54350 is a medium output current synchronous buck PWM converter with an integrated high side MOSFET and a gate driver for an optional low side external MOSFET. Features include a high performance voltage error amplifier that enables maximum performance under transient conditions and flexibility in choosing the output filter inductors and capacitors. The TPS54350 has an under-voltage-lockout circuit to prevent start-up until the input voltage reaches 4.5 V; an internal slow-start circuit to limit in-rush currents; and a power good output to indicate valid output conditions. The synchronization feature is configurable as either an input or an output for easy 180° out of phase synchronization.

The TPS54350 device is available in a thermally enhanced 16-pin TSSOP (PWP) PowerPAD™ package. TI provides evaluation modules and the SWIFT™ Designer software tool to aid in quickly achieving high-performance power supply designs to meet aggressive equipment development cycles.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ORDERING INFORMATION

T _A	OUTPUT VOLTAGE	PACKAGE	PART NUMBER
–40°C to 85°C	Adjustable to 0.891 V	Plastic HTSSOP (PWP)	TPS54350PWP

(1) The PWP package is also available taped and reeled. Add an R suffix to the device type (i.e. TPS54350PWPR).

PACKAGE DISSIPATION RATINGS(1)

PACKAGE	THERMAL IMPEDANCE JUNCTION-TO-AMBIENT	T _A = 25°C POWER RATING	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
16-Pin PWP with solder(2)	42.1°C/W	2.36	1.31	0.95
16-Pin PWP without solder	151.9°C/W	0.66	0.36	0.26

(1) See Figure 46 for power dissipation curves.

(2) Test Board Conditions

1. Thickness: 0.062"
2. 3" x 3"
3. 2 oz. Copper traces located on the top and bottom of the PCB for soldering
4. Copper areas located on the top and bottom of the PCB for soldering
5. Power and Ground planes, 1 oz. Copper (0.036 mm thick)
6. Thermal vias, 0.33 mm diameter, 1.5 mm pitch
7. Thermal isolation of power plane

For more information, refer to TI technical brief SLMA002.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted(1)

		UNIT
Input voltage range, V _I	VIN	–0.3 V to 21.5 V
	VSENSE	–0.3 V to 8.0 V
	UVLO	–0.3 V to 8.0 V
	SYNC	–0.3 V to 4.0 V
	ENA	–0.3 V to 4.0 V
	BOOT	V _I (PH) + 8.0 V
Output voltage range, V _O	VBIAS	–0.3 to 8.5 V
	LSG	–0.3 to 8.5 V
	SYNC	–0.3 to 4.0 V
	RT	–0.3 to 4.0 V
	PWRGD	–0.3 to 6.0 V
	COMP	–0.3 to 4.0 V
	PH	–1.5 V to 22 V
Source current, I _O	PH	Internally Limited (A)
	LSG (Steady State Current)	10 mA
	COMP, VBIAS	3 mA
Sink current, I _S	SYNC	5 mA
	LSG (Steady State Current)	100 mA
	PH (Steady State Current)	500 mA
	COMP	3 mA
	ENA, PWRGD	10 mA
Voltage differential	AGND to PGND	±0.3 V
Operating virtual junction temperature range, T _J		–40°C to +150°C
Storage temperature, T _{stg}		–65°C to +150°C
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds		260°C

(1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

	MIN	NOM	MAX	UNIT
Input voltage range, V_I	4.5		20	V
Operating junction temperature, T_J	-40		125	°C

ELECTRICAL CHARACTERISTICS

 $T_J = -40^{\circ}\text{C}$ to 125°C , $V_{IN} = 4.5\text{ V}$ to 20 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I _Q Quiescent current		Operating Current, PH Pin open, No external low side MOSFET, RT = Hi-Z	5			mA
		Shutdown, ENA = 0 V	1.0			mA
VIN	Start threshold voltage		4.32	4.49		V
	Stop threshold voltage		3.69	3.97		V
	Hysteresis		350			mV
UNDER VOLTAGE LOCK OUT (UVLO PIN)						
UVLO	Start threshold voltage		1.20	1.24		V
	Stop threshold voltage		1.02	1.10		V
	Hysteresis		100			mV
BIAS VOLTAGE (VBIAS PIN)						
VBIAS Output voltage	I _{VBIAS} = 1 mA, VIN ≥ 12 V		7.5	7.8	8.0	V
	I _{VBIAS} = 1 mA, VIN = 4.5 V		4.4	4.47	4.5	
REFERENCE SYSTEM ACCURACY						
Reference voltage		T _J = 25°C	0.888	0.891	0.894	V
			0.882	0.891	0.899	V
OSCILLATOR (RT PIN)						
Internally set PWM switching frequency		RT Grounded	200	250	300	kHz
		RT Open	400	500	600	
Externally set PWM switching frequency		RT = 100 kΩ (1% resistor to AGND)	425	500	575	kHz
FALLING EDGE TRIGGERED BIDIRECTIONAL SYNC SYSTEM (SYNC PIN)						
SYNC out low-to-high rise time (10%/90%) ⁽¹⁾		25 pF to ground	200	500		ns
SYNC out high-to-low fall time (90%/10%) ⁽¹⁾		25 pF to ground	5	10		ns
Falling edge delay time ⁽¹⁾		Delay from rising edge to rising edge of PH pins, see Figure 19	180			°
Minimum input pulsewidth ⁽¹⁾		RT = 100 kΩ	100			ns
Delay (falling edge SYNC to rising edge PH) ⁽¹⁾		RT = 100 kΩ	360			ns
SYNC out high level voltage		50 kΩ resistor to ground, no pullup resistor	2.5			V
SYNC out low level voltage				0.6		V
SYNC in low level threshold			0.8			V
SYNC in high level threshold				2.3		V
SYNC in frequency range ⁽¹⁾		Percentage of programmed frequency	–10%	10%		
			225	770		kHz

⁽¹⁾ Ensured by design, not production tested.

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ELECTRICAL CHARACTERISTICS

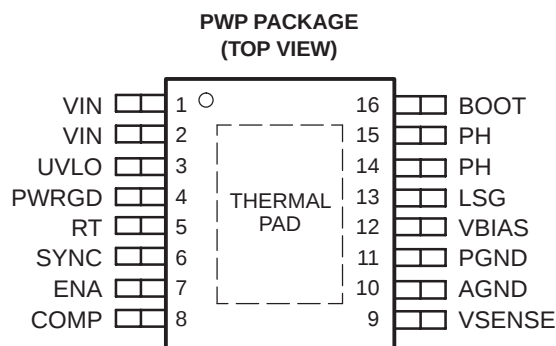
 $T_J = -40^{\circ}\text{C}$ to 125°C , $V_{IN} = 4.5\text{ V}$ to 20 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
FEED– FORWARD MODULATOR (INTERNAL SIGNAL)						
Modulator gain		VIN = 12 V, TJ = 25°C	8			V/V
Modulator gain variation			–25%	25%		
Minimum controllable ON time (1)			180			ns
Maximum duty factor (1)		VIN = 4.5 V	80%	86%		
ERROR AMPLIFIER (VSENSE AND COMP PINS)						
Error amplifier open loop voltage gain (1)			60	80		dB
Error amplifier unity gain bandwidth (1)			1.0	2.8		MHz
Input bias current, VSENSE pin			500			nA
COMP	Output voltage slew rate (symmetric) (1)		1.5			V/μs
ENABLE (ENA PIN)						
Disable low level input voltage			0.5			V
Internal slow-start time (10% to 90%)		fS = 250 kHz, RT = ground (1)	4.6			ms
		fS = 500 kHz, RT = Hi–Z (1)	2.3			
Pullup current source			1.8	5	10	μA
Pulldown MOSFET		II(ENA)=1 mA	0.1			V
POWER GOOD (PWRGD PIN)						
Power good threshold		Rising voltage	97%			
Rising edge delay (1)		fS = 250 kHz	4			ms
		fS = 500 kHz	2			
PWRGD	Output saturation voltage	ISink = 1 mA, VIN > 4.5 V	0.05			V
	Output saturation voltage	ISink = 100 μA, VIN = 0 V	0.76			V
	Open drain leakage current	Voltage on PWRGD = 6 V	3			μA
CURRENT LIMIT						
Current limit		VIN = 12 V	3.3	4.5	6.5	A
Current limit Hiccup Time (1)		fS = 500 kHz	4.5			ms
THERMAL SHUTDOWN						
Thermal shutdown trip point (1)			165			°C
Thermal shutdown hysteresis (1)			7			°C
LOW SIDE MOSFET DRIVER (LSG PIN)						
Turn on rise time, (10%/90%) (1)		VIN = 4.5 V, Capacitive load = 1000 pF	15			ns
Deadtime (1)		VIN = 12 V	60			ns
Driver ON resistance		VIN = 4.5 V sink/source	7.5			Ω
		VIN = 12 V sink/source	5			
OUTPUT POWER MOSFETS (PH PIN)						
Phase node voltage when disabled		DC conditions and no load, ENA = 0 V	0.5			V
Voltage drop, low side FET and diode		VIN = 4.5 V, Idc = 100 mA	1.13	1.42		V
		VIN = 12 V, Idc = 100 mA	1.08	1.38		
rDS(ON), high side power MOSFET switch(2)		VIN = 4.5 V, BOOT–PH = 4.5 V, IO = 0.5 A	150	300		mΩ
		VIN = 12 V, BOOT–PH = 8 V, IO = 0.5 A	100	200		

(1) Ensured by design, not production tested.

(2) Resistance from V_{IN} to PH pins.

PIN ASSIGNMENTS



NOTE: If there is not a Pin 1 indicator, turn device to enable reading the symbol from left to right. Pin 1 is at the lower left corner of the device.

Terminal Functions

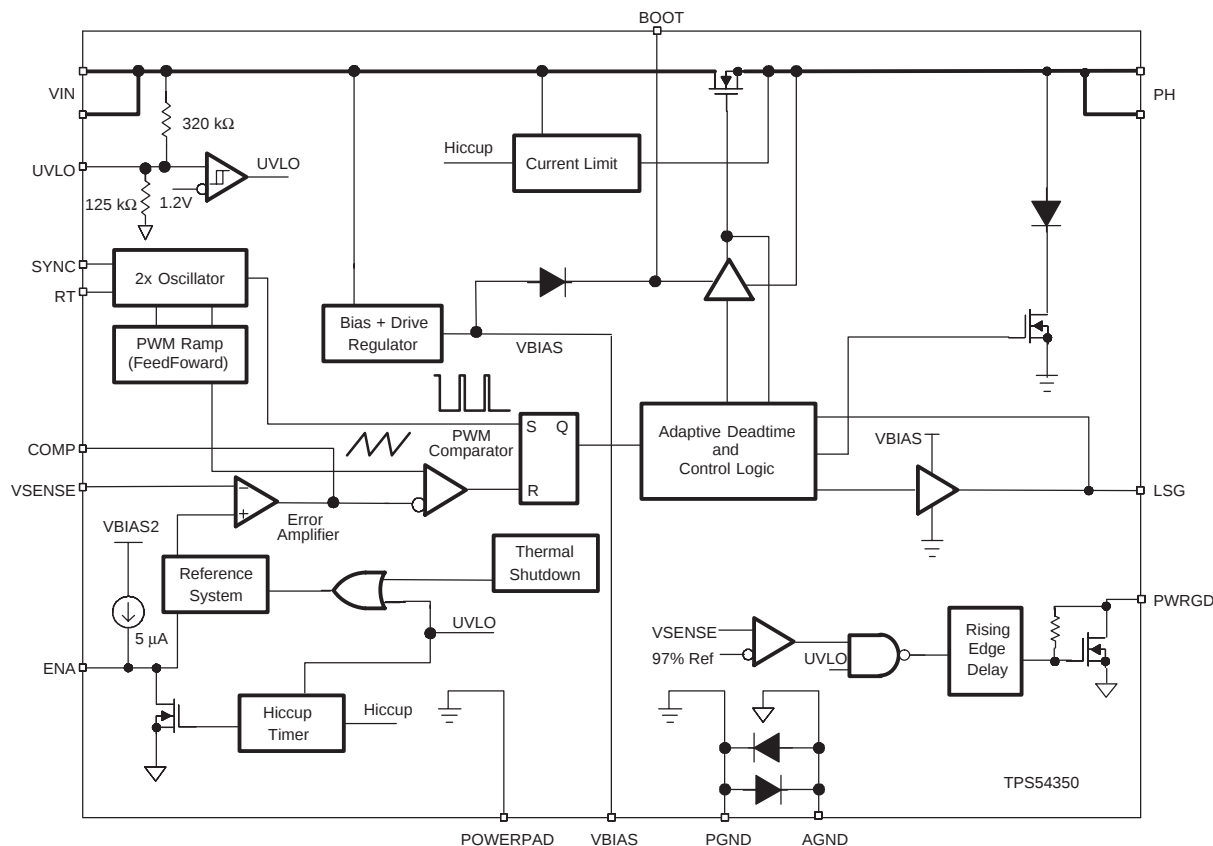
TERMINAL NO.	NAME	DESCRIPTION
1, 2	VIN	Input supply voltage, 4.5 V to 20 V. Must bypass with a low ESR 10- μ F ceramic capacitor.
3	UVLO	Undervoltage lockout pin. Connecting an external resistive voltage divider from VIN to the pin will override the internal default VIN start and stop thresholds.
4	PWRGD	Power good output. Open drain output. A low on the pin indicates that the output is less than the desired output voltage. There is an internal rising edge filter on the output of the PWRGD comparator.
5	RT	Frequency setting pin. Connect a resistor from RT to AGND to set the switching frequency. Connecting the RT pin to ground or floating will set the frequency to an internally preselected frequency.
6	SYNC	Bidirectional synchronization I/O pin. SYNC pin is an output when the RT pin is floating or connected low. The output is a falling edge signal out of phase with the rising edge of PH. SYNC may be used as an input to synchronize to a system clock by connecting to a falling edge signal when an RT resistor is used. See 180° Out of Phase Synchronization operation in the Application Information section.
7	ENA	Enable. Below 0.5 V, the device stops switching. Float pin to enable.
8	COMP	Error amplifier output. Connect frequency compensation network from COMP to VSENSE pins.
9	VSENSE	Inverting node error amplifier.
10	AGND	Analog ground—internally connected to the sensitive analog ground circuitry. Connect to PGND and PowerPAD.
11	PGND	Power Ground—Noisy internal ground—Return currents from the LSG driver output return through the PGND pin. Connect to AGND and PowerPAD.
12	VBIAS	Internal 8.0V bias voltage. A 1.0 μ F ceramic bypass capacitance is required on the VBIAS pin.
13	LSG	Gate drive for optional low side MOSFET. Connect gate of n-channel MOSFET for a higher efficiency synchronous buck converter configuration. Otherwise, leave open and connect schottky diode from ground to PH pins.
14, 15	PH	Phase node—Connect to external L-C filter.
16	BOOT	Bootstrap capacitor for high side gate driver. Connect 0.1 μ F ceramic capacitor from BOOT to PH pins.
	PowerPAD	PGND and AGND pins must be connected to the exposed pad for proper operation. See Figure 21 for an example PCB layout.

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APPLICATION INFORMATION

FUNCTIONAL BLOCK DIAGRAM



DETAILED DESCRIPTION

Undervoltage Lockout (UVLO)

The undervoltage lockout (UVLO) system has an internal voltage divider from VIN to AGND. The defaults for the start/stop values are labeled VIN and given in Table 1. The internal UVLO threshold can be overridden by placing an external resistor divider from VIN to ground. The internal divider values are approximately 320 kΩ for the high side resistor and 125 kΩ for the low side resistor. The divider ratio (and therefore the default start/stop values) is quite

accurate, but the absolute values of the internal resistors may vary as much as 15%. If high accuracy is required for an externally adjusted UVLO threshold, select lower value external resistors to set the UVLO threshold. Using a 1-kΩ resistor for the low side resistor (R2 see Figure 1) is recommended. Under no circumstances should the UVLO pin be connected directly to VIN.

Table 1. Start/Stop Voltage Threshold

	START VOLTAGE THRESHOLD	STOP VOLTAGE THRESHOLD
VIN (Default)	4.49	3.69
UVLO	1.24	1.02

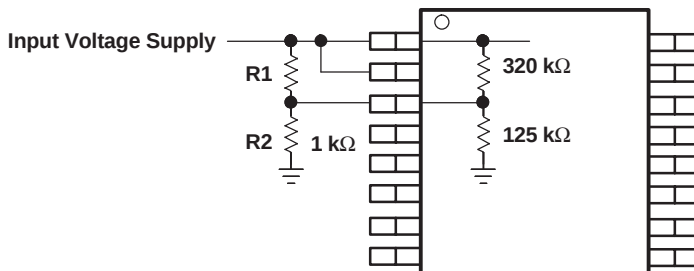


Figure 1. Circuit Using External UVLO Function

The equations for selecting the UVLO resistors are:

$$R1 = \frac{VIN(start) \times 1 \text{ k}\Omega}{1.24 \text{ V}} - 1 \text{ k}\Omega \quad (1)$$

$$VIN(stop) = \frac{(R1 + 1 \text{ k}\Omega) \times 1.02 \text{ V}}{1 \text{ k}\Omega} \quad (2)$$

For applications which require an undervoltage lock out (UVLO) threshold greater than 4.49 V, external resistors may be implemented, see Figure 1, to adjust the start voltage threshold. For example, an application needing an UVLO start voltage of approximately 7.8 V using the equation (1), R1 is calculated to the nearest standard resistor value of 5.36 kΩ. Using equation (2), the input voltage stop threshold is calculated as 6.48 V.

Enable (ENA) and Internal Slow Start

Once the ENA pin voltage exceeds 0.5 V, the TPS54350 starts operation. The TPS54350 has an internal digital slow start that ramps the reference voltage to its final value in 1150 switching cycles. The internal slow start time (10% – 90%) is approximated by the following expression:

$$T_{SS_INTERNAL}(ms) = \frac{1.15k}{f_s(kHz)} \quad (3)$$

Once the TPS54350 device is in normal regulation, the ENA pin is high. If the ENA pin is pulled below the stop threshold of 0.5 V, switching stops and the internal slow start resets. If an application requires the TPS54350 to be disabled, use open drain or open collector output logic to interface to the ENA pin (see Figure 2). The ENA pin has an internal pullup current source. Do not use external pullup resistors.

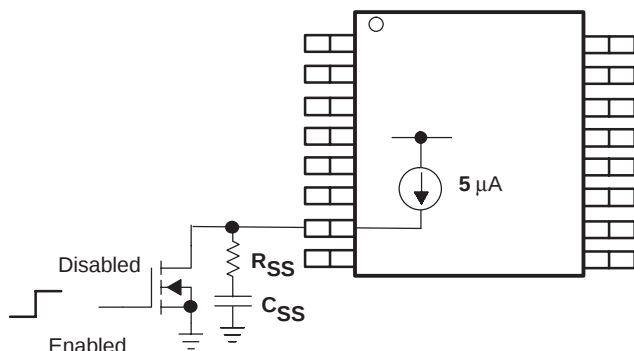


Figure 2. Interfacing to the ENA Pin

Extending Slow Start Time

In applications that use large values of output capacitance there may be a need to extend the slow start time to prevent the startup current from tripping the current limit. The current limit circuit is designed to disable the high side MOSFET and reset the internal voltage reference for a short amount of time when the high side MOSFET current exceeds the current limit threshold. If the output capacitance and load current cause the startup current to exceed the current limit threshold, the power supply output will not reach the desired output voltage. To extend the slow start time and to reduce the startup current, an external resistor and capacitor can be added to the ENA pin. The slow start capacitance is calculated using the following equation:

$$C_{SS}(\mu F) = 5.55e^{-3} T_{SS}(ms)$$

The R_{SS} resistor must be 2 kΩ and the slow start capacitor must be less than 0.47 μF.

Switching Frequency (RT)

The TPS54350 has an internal oscillator that operates at twice the PWM switching frequency. The internal oscillator frequency is controlled by the RT pin. Grounding the RT pin sets the PWM switching frequency to a default frequency of 250 kHz. Floating the RT pin sets the PWM switching frequency to 500 kHz.

Connecting a resistor from RT to AGND sets the frequency according to the following equation (also see Figure 30).

$$RT(k\Omega) = \frac{46000}{f_s(kHz) - 35.9} \quad (4)$$

The RT pin controls the SYNC pin functions. If the RT pin is floating or grounded, SYNC is an output. If the switching frequency has been programmed using a resistor from RT to AGND, then SYNC functions as an input.

The internal voltage ramp charging current increases linearly with the set frequency and keeps the feed forward modulator constant (K_m = 8) regardless of the frequency set point.

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SWITCHING FREQUENCY	SYNC PIN	RT PIN
250 kHz, internally set	Generates SYNC output signal	AGND
500 kHz, internally set	Generates SYNC output signal	Float
Externally set to 250 kHz to 700 kHz	Terminate to quiet ground with 10-k Ω resistor.	R = 215 k Ω to 69 k Ω
Externally synchronized frequency	Synchronization Signal	Use 110 k Ω when RT floats and 237 k Ω when RT is grounded and using the sync out signal of another TPS54350. Set RT resistor equal to 90% to 110% of external synchronization frequency.

180° Out of Phase Synchronization (SYNC)

The SYNC pin is configurable as an input or as an output, per the description in the previous section. When operating as an input, the SYNC pin is a falling-edge triggered signal (see Figures 3, 4, and 19). When operating as an output, the signal's falling edge is approximately 180° out of phase with the rising edge of the PH pins. Thus, two TPS54350 devices operating in a system can share an input capacitor and draw ripple current at twice the frequency of a single unit.

When operating the two TPS54350 devices 180° out of

phase, the total RMS input current is reduced. Thus reducing the amount of input capacitance needed and increasing efficiency.

When synchronizing a TPS54350 to an external signal, the timing resistor on the RT pin must be set so that the oscillator is programmed to run at 90% to 110% of the synchronization frequency.

NOTE:

Do not use synchronization input for designs with output voltages > 10 V.

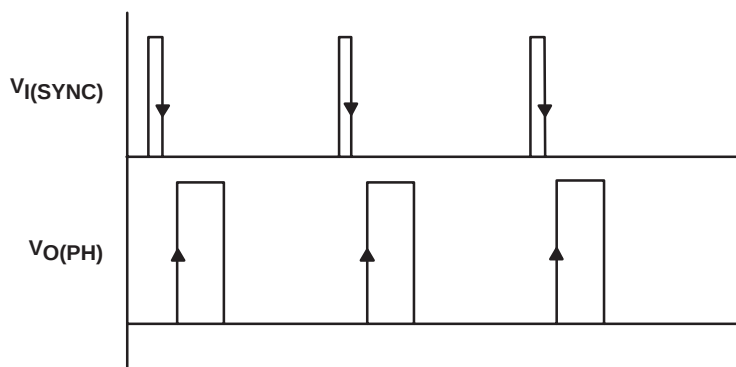


Figure 3. SYNC Input Waveform

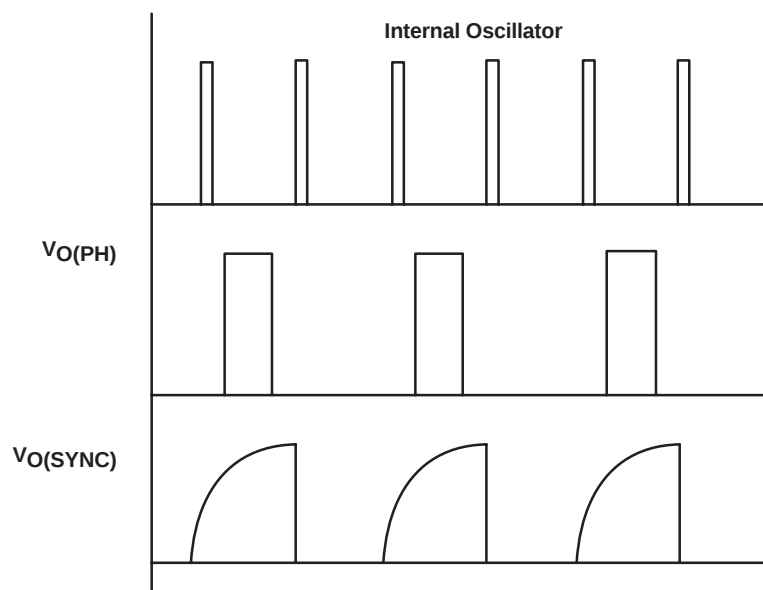


Figure 4. SYNC Output Waveform

Power Good (PWRGD)

The VSENSE pin is compared to an internal reference signal, if the VSENSE is greater than 97% and no other faults are present, the PWRGD pin presents a high impedance. A low on the PWRGD pin indicates a fault. The PWRGD pin has been designed to provide a weak pull-down and indicates a fault even when the device is unpowered. If the TPS54350 has power and has any fault flag set, the TPS54350 indicates the power is not good by driving the PWRGD pin low. The following events, singly or in combination, indicate power is not good:

- VSENSE pin out of bounds
- Overcurrent
- Thermal shutdown
- UVLO undervoltage
- Input voltage not present (weak pull-down)
- Slow-starting
- VBIAS voltage is low

Once the PWRGD pin presents a high impedance (i.e., power is good), a VSENSE pin out of bounds condition forces PWRGD pin low (i.e., power is bad) after a time delay. This time delay is a function of the switching frequency and is calculated using equation 5:

$$T_{\text{delay}} = \frac{1000}{f_{\text{s}}(\text{kHz})} \text{ ms} \quad (5)$$

Bias Voltage (VBIAS)

The VBIAS regulator provides a stable supply for the internal analog circuits and the low side gate driver. Up to 1 mA of current can be drawn for use in an external application circuit. The VBIAS pin must have a bypass capacitor value of 1.0 μF . X7R or X5R grade dielectric ceramic capacitors are recommended because of their stable characteristics over temperature.

Bootstrap Voltage (BOOT)

The BOOT capacitor obtains its charge cycle by cycle from the VBIAS capacitor. A capacitor from the BOOT pin to the PH pins is required for operation. The bootstrap connection for the high side driver must have a bypass capacitor of 0.1 μF .

Error Amplifier

The VSENSE pin is the error amplifier inverting input. The error amplifier is a true voltage amplifier with 1.5 mA of drive capability with a minimum of 60 dB of open loop voltage gain and a unity gain bandwidth of 2 MHz.

Voltage Reference

The voltage reference system produces a precision reference signal by scaling the output of a temperature stable bandgap circuit. During production testing, the

bandgap and scaling circuits are trimmed to produce 0.891 V at the output of the error amplifier, with the amplifier connected as a voltage follower. The trim procedure improves the regulation, since it cancels offset errors in the scaling and error amplifier circuits.

PWM Control and Feed Forward

Signals from the error amplifier output, oscillator, and current limit circuit are processed by the PWM control logic. Referring to the internal block diagram, the control logic includes the PWM comparator, PWM latch, and the adaptive dead-time control logic. During steady-state operation below the current limit threshold, the PWM comparator output and oscillator pulse train alternately reset and set the PWM latch.

Once the PWM latch is reset, the low-side driver and integrated pull-down MOSFET remain on for a minimum duration set by the oscillator pulse width. During this period, the PWM ramp discharges rapidly to the valley voltage. When the ramp begins to charge back up, the low-side driver turns off and the high-side FET turns on. The peak PWM ramp voltage varies inversely with input voltage to maintain a constant modulator and power stage gain of 8 V/V.

As the PWM ramp voltage exceeds the error amplifier output voltage, the PWM comparator resets the latch, thus turning off the high-side FET and turning on the low-side FET. The low-side driver remains on until the next oscillator pulse discharges the PWM ramp.

During transient conditions, the error amplifier output can be below the PWM ramp valley voltage or above the PWM peak voltage. If the error amplifier is high, the PWM latch is never reset and the high-side FET remains on until the oscillator pulse signals the control logic to turn the high-side FET off and the internal low-side FET and driver on. The device operates at its maximum duty cycle until the output voltage rises to the regulation set point, setting VSENSE to approximately the same voltage as the internal voltage reference. If the error amplifier output is low, the PWM latch is continually reset and the high-side FET does not turn on. The internal low-side FET and low side driver remain on until the VSENSE voltage decreases to a range that allows the PWM comparator to change states. The TPS54350 is capable of sinking current through the external low side FET until the output voltage reaches the regulation set point.

The minimum on time is designed to be 180 ns. During the internal slow-start interval, the internal reference ramps from 0 V to 0.891 V. During the initial slow-start interval, the internal reference voltage is very small resulting in a couple of skipped pulses because the minimum on time causes the actual output voltage to be slightly greater than the preset output voltage until the internal reference ramps up.

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Deadtime Control

Adaptive dead time control prevents shoot through current from flowing in the integrated high-side MOSFET and the external low-side MOSFET during the switching transitions by actively controlling the turn on times of the drivers. The high-side driver does not turn on until the voltage at the gate of the low-side MOSFET is below 1 V. The low-side driver does not turn on until the voltage at the gate of the high-side MOSFET is below 1 V.

Low Side Gate Driver (LSG)

LSG is the output of the low-side gate driver. The 100-mA MOSFET driver is capable of providing gate drive for most popular MOSFETs suitable for this application. Use the SWIFT Designer Software Tool to find the most appropriate MOSFET for the application. Connect the LSG pin directly to the gate of the low-side MOSFET. Do not use a gate resistor as the resulting turn-on time may be too slow.

Integrated Pulldown MOSFET

The TPS54350 has a diode-MOSFET pair from PH to PGND. The integrated MOSFET is designed for light-load continuous-conduction mode operation when only an external Schottky diode is used. The combination of devices keeps the inductor current continuous under conditions where the load current drops below the inductor's critical current. Care should be taken in the selection of inductor in applications using only a low-side Schottky diode. Since the inductor ripple current flows through the integrated low-side MOSFET at light loads, the inductance value should be selected to limit the peak current to less than 0.3 A during the high-side FET turn off time. The minimum value of inductance is calculated using the following equation:

$$L(H) = \frac{VO \times \left(1 - \frac{VO}{VI}\right)}{f_s \times 0.6} \quad (6)$$

Thermal Shutdown

The device uses the thermal shutdown to turn off the MOSFET drivers and controller if the junction temperature exceeds 165°C. The device is restarted automatically when the junction temperature decreases to 7°C below the thermal shutdown trip point and starts up under control of the slow-start circuit.

Overcurrent Protection

Overcurrent protection is implemented by sensing the drain-to-source voltage across the high-side MOSFET and compared to a voltage level which represents the overcurrent threshold limit. If the drain-to-source voltage exceeds the overcurrent threshold limit for more than

100 ns, the ENA pin is pulled low, the high-side MOSFET is disabled, and the internal digital slow-start is reset to 0 V. ENA is held low for approximately the time that is calculated by the following equation:

$$T_{HICCUP(ms)} = \frac{2250}{f_s(kHz)} \quad (7)$$

Once the hiccup time is complete, the ENA pin is released and the converter initiates the internal slow-start.

Setting the Output Voltage

The output voltage of the TPS54350 can be set by feeding back a portion of the output to the VSENSE pin using a resistor divider network. In the application circuit of Figure 24, this divider network is comprised of resistors R1 and R2. To calculate the resistor values to generate the required output voltage use the following equation:

$$R2 = \frac{R1 \times 0.891}{V_o - 0.891} \quad (8)$$

Start with a fixed value of R1 and calculate the required R2 value. Assuming a fixed value of 10 kΩ for R1, the following table gives the appropriate R2 value for several common output voltages:

OUTPUT VOLTAGE (V)	R2 VALUE (KΩ)
1.2	28.7
1.5	14.7
1.8	9.76
2.5	5.49
3.3	3.74

Output Voltage Limitations

Due to the internal design of the TPS54350 there are both upper and lower output voltage limits for any given input voltage. Additionally, the lower boundary of the output voltage set point range is also dependent on operating frequency. The upper limit of the output voltage set point is constrained by the maximum duty cycle of the device and is shown in Figure 48. The lower limit is constrained by the minimum controllable on time which may be as high as 220 ns. The approximate minimum output voltage for a given input voltage and range of operating frequencies is shown in Figure 29 while the maximum operating frequency versus input voltage for some common output voltages is shown in Figure 30.

The curves shown in these two figures are valid for output currents greater than 0.5 A. As output currents decrease towards no load (0 A), the minimum output voltage decreases. For applications where the load current is less than 100 mA, the curves shown in Figures 31 and 32 are applicable. All of the data plotted in these curves are approximate and take into account a possible 20 percent deviation in actual operating frequency relative to the intended set point.

TYPICAL CHARACTERISTICS

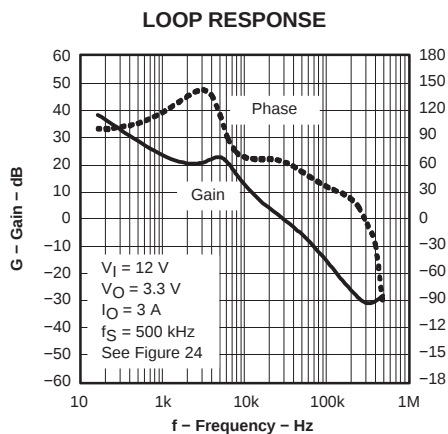


Figure 5

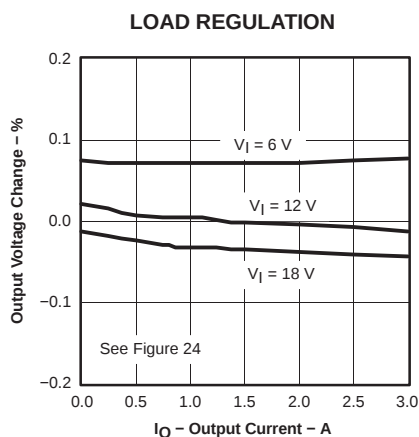


Figure 6

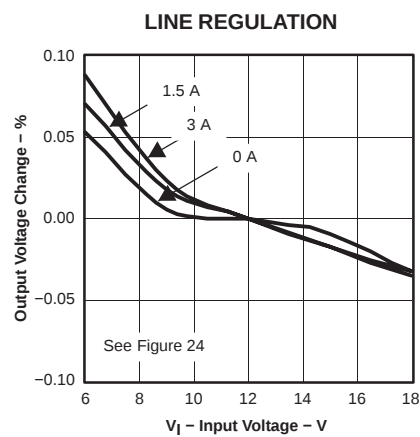


Figure 7

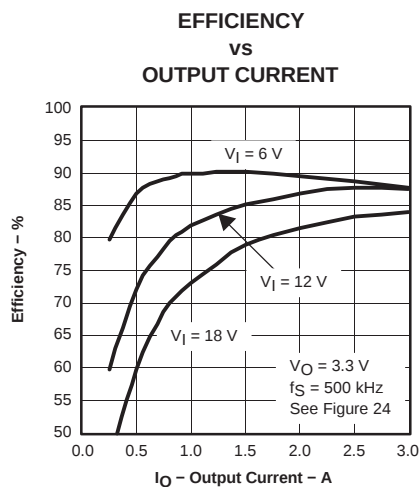


Figure 8

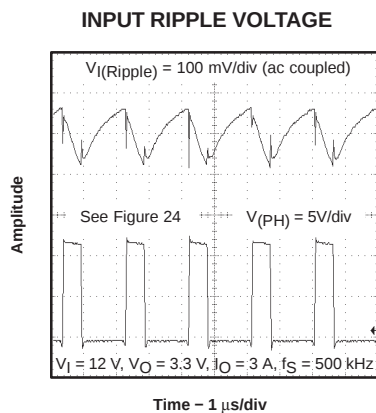


Figure 9

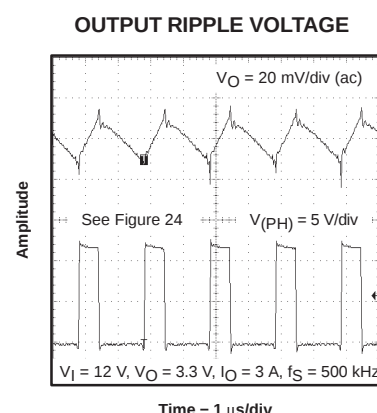


Figure 10

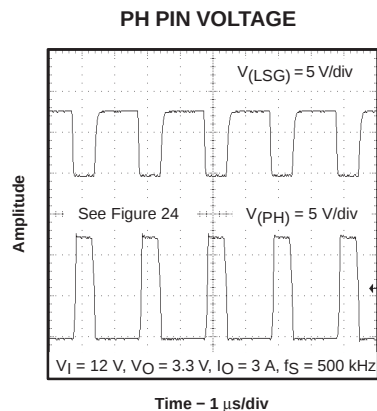


Figure 11

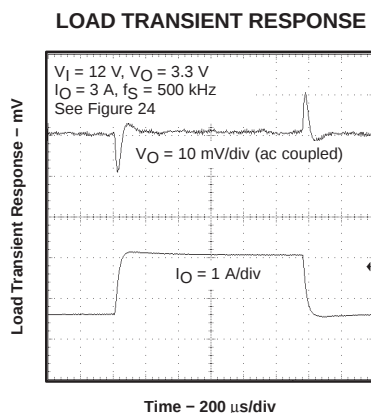


Figure 12

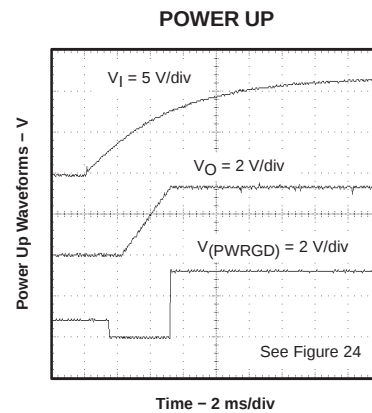


Figure 13

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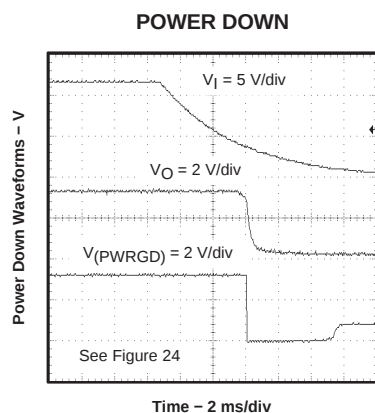


Figure 14

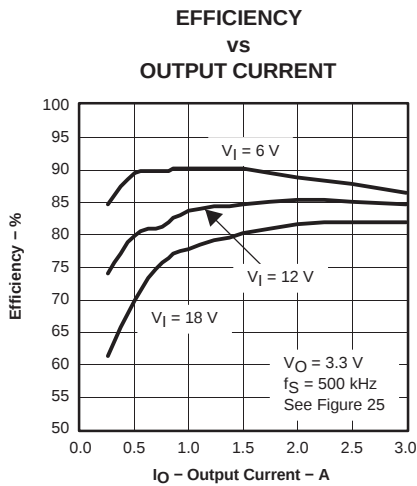


Figure 15

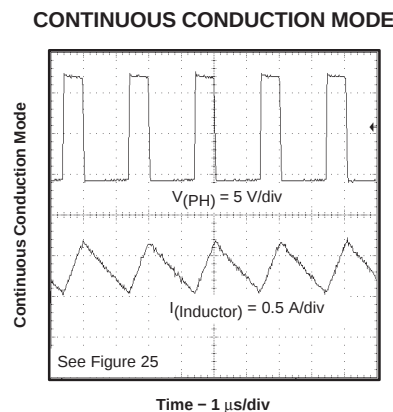


Figure 16

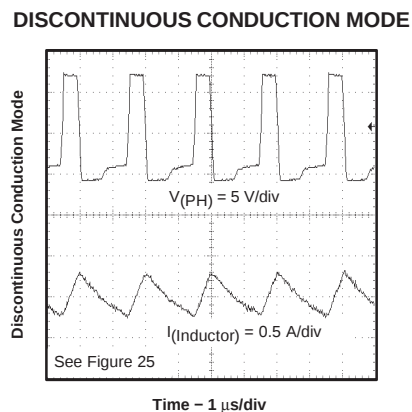


Figure 17

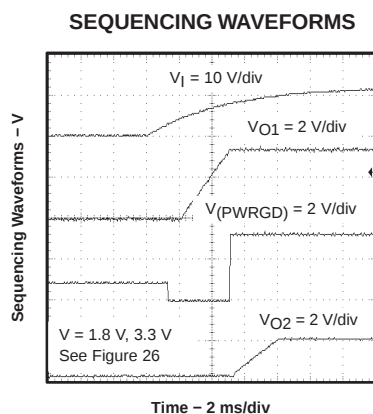


Figure 18

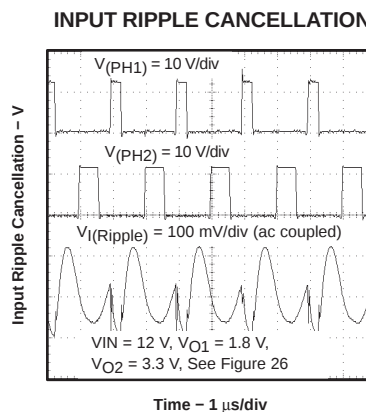


Figure 19

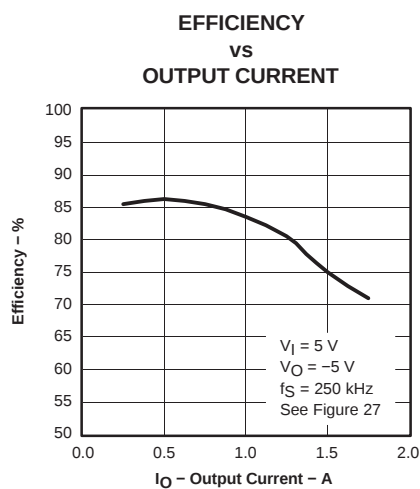


Figure 20

APPLICATION INFORMATION

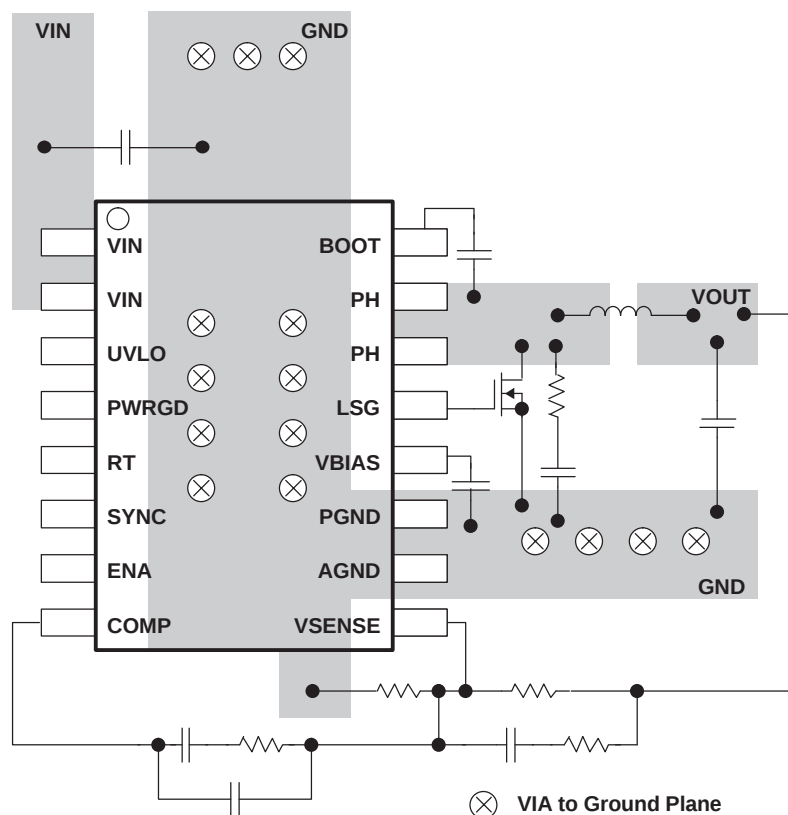


Figure 21. TPS54350 PCB Layout

PCB LAYOUT

The VIN pins should be connected together on the printed circuit board (PCB) and bypassed with a low ESR ceramic bypass capacitor. Care should be taken to minimize the loop area formed by the bypass capacitor connections, the VIN pins, and the TPS54350 ground pins. The minimum recommended bypass capacitance is 10- μ F ceramic with a X5R or X7R dielectric and the optimum placement is closest to the VIN pins and the AGND and PGND pins. See Figure 21 for an example of a board layout. The AGND and PGND pins should be tied to the PCB ground plane at the pins of the IC. The source of the low-side MOSFET and the anode of the Schottky diode should be connected directly to the PCB ground plane. The PH pins should be tied together and routed to the drain of the low-side MOSFET or to the cathode of the external Schottky diode. Since the PH connection is the switching node, the MOSFET (or diode) should be located very close to the PH pins, and the area of the PCB conductor minimized to prevent excessive capacitive coupling. The recommended conductor width from pins 14 and 15 is 0.050 inch to 0.075 inch of 1-ounce

copper. The length of the copper land pattern should be no more than 0.2 inch.

For operation at full rated load, the analog ground plane must provide adequate heat dissipating area. A 3-inch by 3-inch plane of copper is recommended, though not mandatory, dependent on ambient temperature and airflow. Most applications have larger areas of internal ground plane available, and the PowerPAD should be connected to the largest area available. Additional areas on the bottom or top layers also help dissipate heat, and any area available should be used when 3 A or greater operation is desired. Connection from the exposed area of the PowerPAD to the analog ground plane layer should be made using 0.013-inch diameter vias to avoid solder wicking through the vias. Four vias should be in the PowerPAD area with four additional vias outside the pad area and underneath the package. Additional vias beyond those recommended to enhance thermal performance should be included in areas not under the device package.

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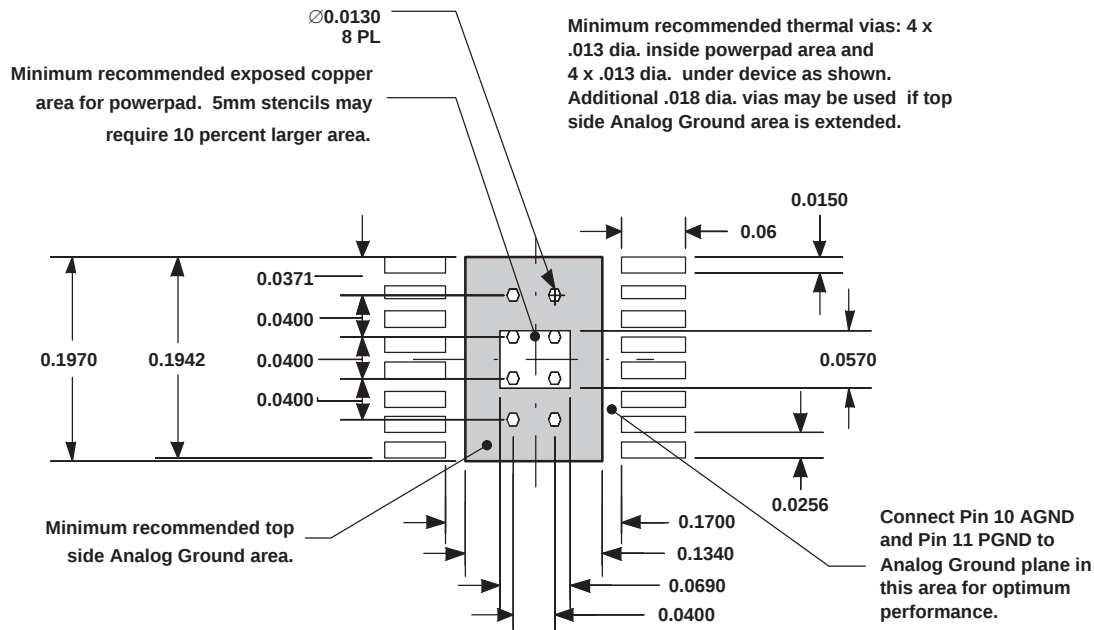


Figure 22. Thermal Considerations for PowerPAD Layout

MODEL FOR LOOP RESPONSE

The Figure 23 shows an equivalent model for the TPS54350 control loop which can be modeled in a circuit simulation program to check frequency response and dynamic load response. The error amplifier in the TPS54350 is a voltage amplifier with 80 dB (10000 V/V) of open loop gain. The error amplifier can be modeled using an ideal voltage-controlled current source as shown in Figure 23 with a resistor and capacitor on the output. The TPS54350 device has an integrated feed forward compensation circuit which eliminates the impact of the input voltage changes to the overall loop transfer function.

The feed forward gain is modeled as an ideal voltage-controlled voltage source with a gain of 8 V/V. The 1-mV ac voltage between nodes a and b effectively breaks the control loop for the frequency response measurements. Plotting b/c shows the small-signal response of the power stage. Plotting c/a shows the small-signal response of the frequency compensation. Plotting a/b shows the small-signal response of the overall loop. The dynamic load response can be checked by replacing the R_L with a current source with the appropriate load step amplitude and step rate in a time domain analysis.

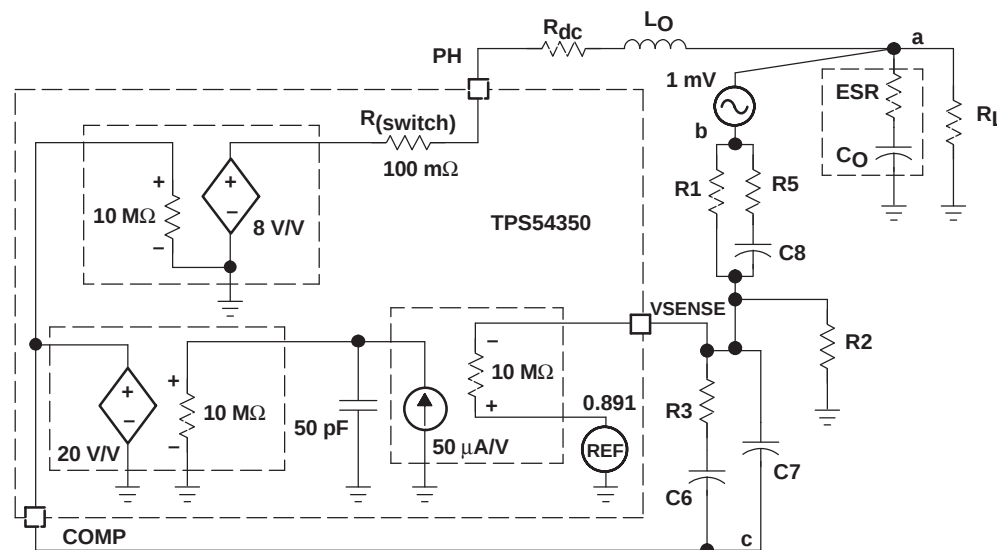


Figure 23. Model of Control Loop

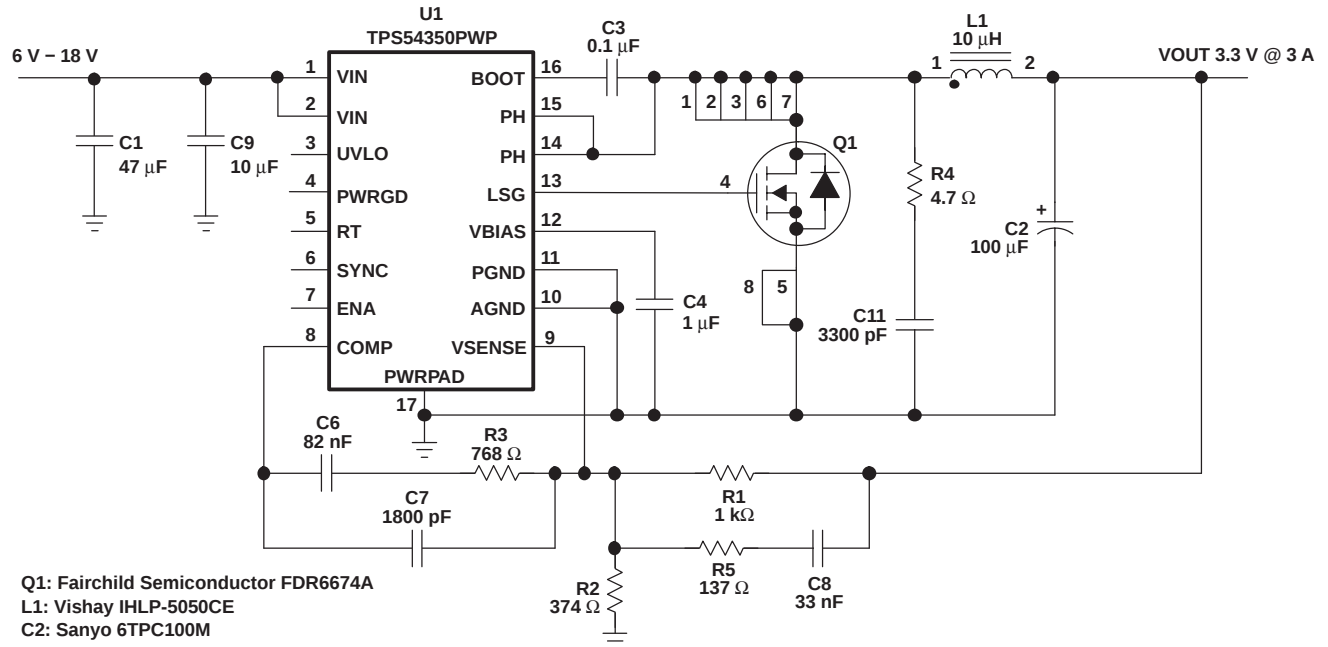


Figure 24. Application Circuit, 12 V to 3.3 V

Figure 24 shows the schematic for a typical TPS54350 application. The TPS54350 can provide up to 3-A output current at a nominal output voltage of 3.3 V. For proper thermal performance, the exposed PowerPAD underneath the device must be soldered down to the printed circuit board.

DESIGN PROCEDURE

The following design procedure can be used to select component values for the TPS54350. Alternately, the SWIFT Designer Software may be used to generate a complete design. The SWIFT Designer Software uses an iterative design procedure and accesses a comprehensive database of components when generating a design. This section presents a simplified discussion of the design process.

DESIGN PROCEDURE

To begin the design process a few parameters must be decided upon. The designer needs to know the following:

- Input voltage range
- Output voltage
- Input ripple voltage
- Output ripple voltage
- Output current rating
- Operating frequency

For this design example, use the following as the input parameters:

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	6 V to 18 V
Output voltage	3.3 V
Input ripple voltage	300 mV
Output ripple voltage	30 mV
Output current rating	3 A
Operating frequency	500 kHz

NOTE: As an additional constraint, the design is set up to be small size and low component height.

SWITCHING FREQUENCY

The switching frequency is set using the RT pin. Grounding the RT pin sets the PWM switching frequency to a default frequency of 250 kHz. Floating the RT pin sets the PWM switching frequency to 500 kHz. By connecting a resistor from RT to AGND, any frequency in the range of 250 to 700 kHz can be set. Use equation 8 to determine the proper value of RT.

$$RT(k\Omega) = \frac{46000}{f_S(kHz) - 35.9} \quad (9)$$

In this example circuit, RT is not connected and the switching frequency is set at 500 kHz.

INPUT CAPACITORS

The TPS54350 requires an input decoupling capacitor and, depending on the application, a bulk input capacitor. The minimum value for the decoupling capacitor, C9, is

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10µF. A high quality ceramic type X5R or X7R is recommended. The voltage rating should be greater than the maximum input voltage. Additionally some bulk capacitance may be needed, especially if the TPS54350 circuit is not located within about 2 inches from the input voltage source. The value for this capacitor is not critical but it also should be rated to handle the maximum input voltage including ripple voltage and should filter the output so that input ripple voltage is acceptable.

This input ripple voltage can be approximated by equation 9:

$$\Delta V_{IN} = \frac{I_{OUT(MAX)} \times 0.25}{C_{BULK} \times f_{SW}} + (I_{OUT(MAX)} \times ESR_{MAX}) \quad (10)$$

Where $I_{OUT(MAX)}$ is the maximum load current, f_{SW} is the switching frequency, C_{BULK} is the bulk capacitor value and ESR_{MAX} is the maximum series resistance of the bulk capacitor.

The maximum RMS ripple current also needs to be checked. For worst case conditions, this can be approximated by equation 10:

$$I_{CIN} = \frac{I_{OUT(MAX)}}{2} \quad (11)$$

In this case the input ripple voltage would be 140 mV and the RMS ripple current would be 1.5 A. The maximum voltage across the input capacitors would be V_{IN} max plus $\Delta V_{IN}/2$. The chosen bulk and bypass capacitors are each rated for 25 V and the combined ripple current capacity is greater than 3 A, both providing ample margin. It is very important that the maximum ratings for voltage and current are not exceeded under any circumstance.

OUTPUT FILTER COMPONENTS

Two components need to be selected for the output filter, L1 and C2. Since the TPS54350 is an externally compensated device, a wide range of filter component types and values can be supported.

Inductor Selection

To calculate the minimum value of the output inductor, use equation 11:

$$L_{MIN} = \frac{V_{OUT(MAX)} \times (V_{IN(MAX)} - V_{OUT})}{V_{IN(max)} \times K_{IND} \times I_{OUT} \times F_{SW}} \quad (12)$$

K_{IND} is a coefficient that represents the amount of inductor ripple current relative to the maximum output current. For designs using low ESR output capacitors such as ceramics, use $K_{IND} = 0.3$. When using higher ESR output capacitors, $K_{IND} = 0.2$ yields better results.

For this design example use $K_{IND} = 0.2$ and the minimum inductor value is calculated to be 8.98 µH. The next highest standard value is 10 µH, which is used in this design.

For the output filter inductor it is important that the RMS current and saturation current ratings not be exceeded. The RMS inductor current can be found from equation 12:

$$I_{L(RMS)} = \sqrt{I_{OUT(MAX)}^2 + \frac{1}{12} \times \left(\frac{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})}{V_{IN(MAX)} \times L_{OUT} \times F_{SW} \times 0.8} \right)^2} \quad (13)$$

and the peak inductor current can be determined with equation 13:

$$I_{L(PK)} = I_{OUT(MAX)} + \frac{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})}{1.6 \times V_{IN(MAX)} \times L_{OUT} \times F_{SW}} \quad (14)$$

For this design, the RMS inductor current is 3.01 A and the peak inductor current is 3.34 A. The chosen inductor is a Vishay IHLP5050CE-01 10 µH. It has a saturation current rating of 14 A and a RMS current rating of 7 A, easily meeting these requirements. A lesser rated inductor could be used, however this device was chosen because of its low profile component height. In general, inductor values for use with the TPS54350 are in the range of 6.8 µH to 47µH.

Capacitor Selection

The important design factors for the output capacitor are dc voltage rating, ripple current rating, and equivalent series resistance (ESR). The dc voltage and ripple current ratings cannot be exceeded. The ESR is important because along with the inductor current it determines the amount of output ripple voltage. The actual value of the output capacitor is not critical, but some practical limits do exist. Consider the relationship between the desired closed loop crossover frequency of the design and LC corner frequency of the output filter. In general, it is desirable to keep the closed loop crossover frequency at less than 1/5 of the switching frequency. With high switching frequencies such as the 500-kHz frequency of this design, internal circuit limitations of the TPS54350 limit the practical maximum crossover frequency to about 50 kHz. Additionally, to allow for adequate phase gain in the compensation network, the LC corner frequency should be about one decade or so below the closed loop crossover frequency. This limits the minimum capacitor value for the output filter to:

$$C_{OUT} = \frac{1}{L_{OUT}} \times \left(\frac{K}{2\pi f_{CO}} \right)^2 \quad (15)$$

Where K is the frequency multiplier for the spread between f_{LC} and f_{CO} . K should be between 5 and 15, typically 10 for one decade difference. For a desired crossover of 50 kHz and a 10-µH inductor, the minimum value for the output capacitor is 100 µF. The selected output capacitor must be

rated for a voltage greater than the desired output voltage plus one half the ripple voltage. Any derating amount must also be included. The maximum RMS ripple current in the output capacitor is given by equation 15:

$$I_{COUT(RMS)} = \frac{1}{\sqrt{12}} \times \left[\frac{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})}{V_{IN(MAX)} \times L_{OUT} \times F_{SW} \times N_C} \right] \quad (16)$$

where N_C is the number of output capacitors in parallel.

The maximum ESR of the output capacitor is determined by the amount of allowable output ripple as specified in the initial design parameters. The output ripple voltage is the inductor ripple current times the ESR of the output filter so the maximum specified ESR as listed in the capacitor data sheet is given by equation 16:

$$ESR_{MAX} = N_C \times \left(\frac{V_{IN(MAX)} \times L_{OUT} \times F_{SW} \times 0.8}{V_{OUT} \times (V_{IN(MAX)} - V_{OUT})} \right) \times \Delta V_{p-p(MAX)} \quad (17)$$

Where ΔV_{p-p} is the desired peak-to-peak output ripple. For this design example, a single 100- μ F output capacitor is chosen for C2 since the design goal is small size. The calculated RMS ripple current is 156 mV and the maximum ESR required is 59 m Ω . A capacitor that meets these requirements is a Sanyo Poscap 6TPC100M, rated at 6.3 V with a maximum ESR of 45 m Ω and a ripple current rating of 1.7 A. An additional small 0.1- μ F ceramic bypass capacitor is also used.

Other capacitor types work well with the TPS54350, depending on the needs of the application.

COMPENSATION COMPONENTS

The external compensation used with the TPS54350 allows for a wide range of output filter configurations. A large range of capacitor values and types of dielectric are supported. The design example uses type 3 compensation consisting of R1, R3, R5, C6, C7 and C8. Additionally, R2 along with R1 forms a voltage divider network that sets the output voltage. These component reference designators are the same as those used in the SWIFT Designer Software. There are a number of different ways to design a compensation network. This procedure outlines a relatively simple procedure that produces good results with most output filter combinations. Use of the SWIFT Designer Software for designs with unusually high closed loop crossover frequencies, low value, low ESR output capacitors such as ceramics or if the designer is unsure about the design procedure is recommended.

When designing compensation networks for the TPS54350, a number of factors need to be considered. The gain of the compensated error amplifier should not be limited by the open loop amplifier gain characteristics and should not produce excessive gain at the switching frequency. Also, the closed loop crossover frequency should be set less than one fifth of the switching frequency, and the phase margin at crossover must be greater than 45 degrees. The general procedure outlined here produces results consistent with these requirements without going into great detail about the theory of loop compensation.

First calculate the output filter LC corner frequency using equation 17:

$$f_{LC} = \frac{1}{2\pi \sqrt{L_{OUT} C_{OUT}}} \quad (18)$$

For the design example, $f_{LC} = 5033$ Hz.

The closed loop crossover frequency should be greater than f_{LC} and less than one fifth of the switching frequency. Also, the crossover frequency should not exceed 50 kHz, as the error amplifier may not provide the desired gain. For this design, a crossover frequency of 30 kHz was chosen. This value is chosen for comparatively wide loop bandwidth while still allowing for adequate phase boost to insure stability.

Next calculate the R2 resistor value for the output voltage of 3.3 V using equation 18:

$$R2 = \frac{R1 \times 0.891}{V_{OUT} - 0.891} \quad (19)$$

For any TPS54350 design, start with an R1 value of 1.0 k Ω . R2 is then 374 Ω .

Now the values for the compensation components that set the poles and zeros of the compensation network can be calculated. Assuming that $R1 > R5$ and $C6 > C7$, the pole and zero locations are given by equations 19 through 22:

$$f_{Z1} = \frac{1}{2\pi R3 C6} \quad (20)$$

$$f_{Z2} = \frac{1}{2\pi R1 C8} \quad (21)$$

$$f_{P1} = \frac{1}{2\pi R5 C8} \quad (22)$$

$$f_{P2} = \frac{1}{2\pi R3 C7} \quad (23)$$

Additionally there is a pole at the origin, which has unity gain with the following frequency:

$$f_{INT} = \frac{1}{2\pi R1 C6} \quad (24)$$

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This pole is used to set the overall gain of the compensated error amplifier and determines the closed loop crossover frequency. Since R1 is given as 1 kΩ and the crossover frequency is selected as 30 kHz, the desired f_{INT} can be calculated with equation 24:

$$f_{INT} = \frac{10^{-0.9} \times f_{CO}}{2} \quad (25)$$

And the value for C6 is given by equation 25:

$$C6 = \frac{1}{2\pi R1 f_{INT}} \quad (26)$$

The first zero, f_{Z1} , is located at one half the output filter LC corner frequency, so R3 can be calculated from:

$$R3 = \frac{1}{\pi C6 f_{LC}} \quad (27)$$

The second zero, f_{Z2} , is located at the output filter LC corner frequency, so C8 can be calculated from:

$$C8 = \frac{1}{2\pi R1 f_{LC}} \quad (28)$$

The first pole, f_{P1} , is located to coincide with the output filter ESR zero frequency. This frequency is given by:

$$f_{ESR} = \frac{1}{2\pi R_{ESR} C_{OUT}} \quad (29)$$

where R_{ESR} is the equivalent series resistance of the output capacitor.

In this case, the ESR zero frequency is 35.4 kHz, and R5 can be calculated from:

$$R5 = \frac{1}{2\pi C8 f_{ESR}} \quad (30)$$

The final pole is placed at a frequency above the closed loop crossover frequency high enough to not cause the phase to decrease too much at the crossover frequency while still providing enough attenuation so that there is little or no gain at the switching frequency. The f_{P2} pole location for this circuit is set to 4 times the closed loop crossover frequency and the last compensation component value C7 can be derived as follows:

$$C7 = \frac{1}{8\pi R3 f_{CO}} \quad (31)$$

Note that capacitors are only available in a limited range of standard values, so the nearest standard value has been chosen for each capacitor. The measured closed loop response for this design is shown in Figure 5.

BIAS AND BOOTSTRAP CAPACITORS

Every TPS54350 design requires a bootstrap capacitor, C3 and a bias capacitor, C4. The bootstrap capacitor must be 0.1 μF. The bootstrap capacitor is located between the PH pins and BOOT pin. The bias capacitor is connected between the VBIAS pin and AGND. The value should be 1.0 μF. Both capacitors should be high quality ceramic types with X7R or X5R grade dielectric for temperature stability. They should be placed as close to the device connection pins as possible.

LOW-SIDE FET

The TPS54350 is designed to operate using an external low-side FET, and the LSG pin provides the gate drive output. Connect the drain to the PH pin, the source to PGND, and the gate to LSG. The TPS54350 gate drive circuitry is designed to accommodate most common n-channel FETs that are suitable for this application. The SWIFT Designer Software can be used to calculate all the design parameters for low-side FET selection. There are some simplified guidelines that can be applied that produce an acceptable solution in most designs.

The selected FET must meet the absolute maximum ratings for the application:

Drain-source voltage (V_{DS}) must be higher than the maximum voltage at the PH pin, which is $V_{INMAX} + 0.5$ V.

Gate-source voltage (V_{GS}) must be greater than 8 V.

Drain current (I_D) must be greater than $1.1 \times I_{OUTMAX}$.

Drain-source on resistance ($r_{DS(on)}$) should be as small as possible, less than 30 mΩ is desirable. Lower values for $r_{DS(on)}$ result in designs with higher efficiencies. It is important to note that the low-side FET on time is typically longer than the high-side FET on time, so attention paid to low-side FET parameters can make a marked improvement in overall efficiency.

Total gate charge (Q_g) must be less than 50 nC. Again, lower Q_g characteristics result in higher efficiencies.

Additionally, check that the device chosen is capable of dissipating the power losses.

For this design, a Fairchild FDR6674A 30-V n-channel MOSFET is used as the low-side FET. This particular FET is specifically designed to be used as a low-side synchronous rectifier.

POWER GOOD

The TPS54350 is provided with a power good output pin PWRGD. This output is an open drain output and is intended to be pulled up to a 3.3-V or 5-V logic supply. A 10-kΩ, pull-up resistor works well in this application. The absolute maximum voltage is 6 V, so care must be taken not to connect this pull-up resistor to VIN if the maximum input voltage exceeds 6 V.

SNUBBER CIRCUIT

R4 and C11 of the application schematic in Figure 24 comprise a snubber circuit. The snubber is included to reduce over-shoot and ringing on the phase node when the internal high-side FET turns on. Since the frequency and

amplitude of the ringing depends to a large degree on parasitic effects, it is best to choose these component values based on actual measurements of any design layout. See literature number SLUP100 for more detailed information on snubber design.

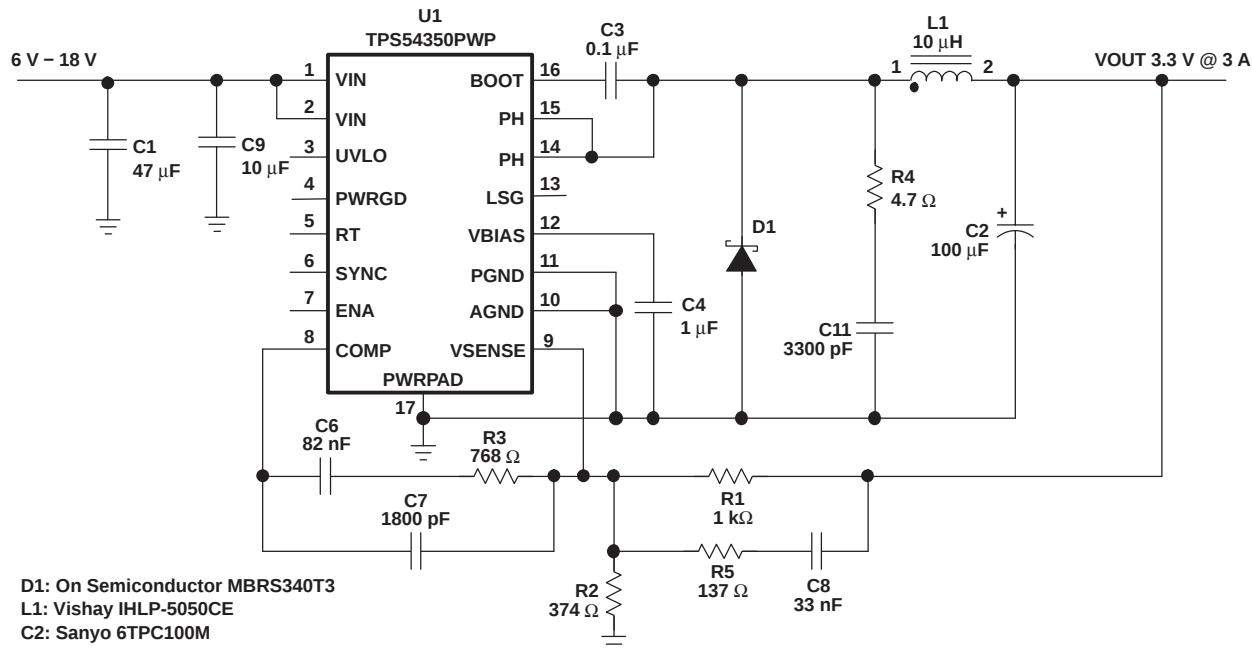


Figure 25. 3.3-V Power Supply With Schottky Diode

Figure 25 shows an application where a clamp diode is used in place of the low-side FET. The TPS54350 incorporates an integrated pull-down FET so that the

circuit remains operating in continuous mode during light load operation. A 3-A, 40-V Schottky diode such as the Motorola MBRS340T3 or equivalent is recommended.

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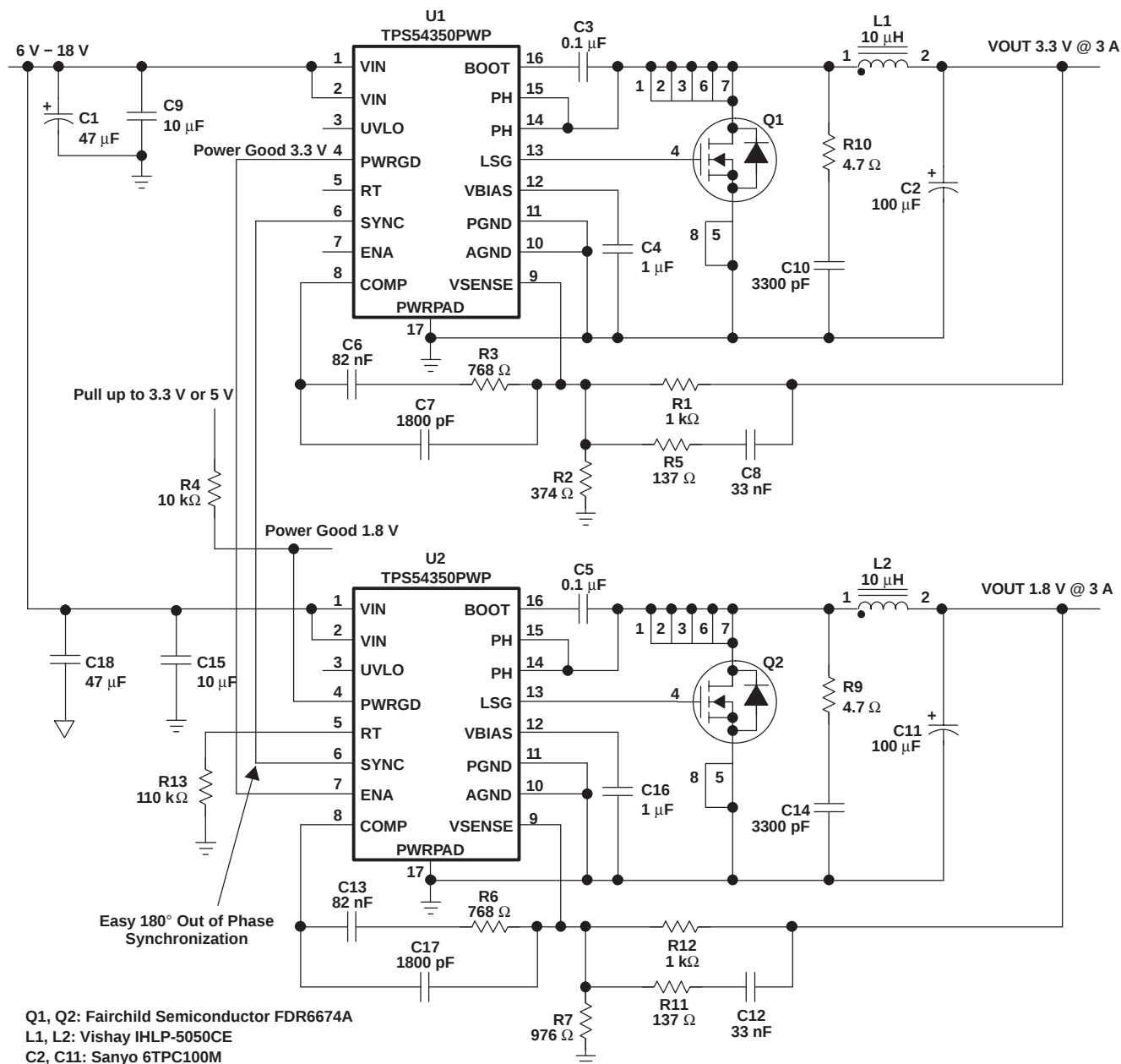


Figure 26. 3.3-V/1.8-V Power Supply With Sequencing

Figure 26 is an example of power supply sequencing using two TPS54350s. U1 is used to generate an output of 3.3 V, while the voltage output of U2 is set at 1.8 V, typical I/O and core voltages for microprocessors and FPGAs. In the circuit, the 3.3-V supply is designed to power up first. The PWRGD pin of U1 is tied to the ENA pin of U2 so that the 1.8-V supply starts to ramp up after the 3.3-V supply is within regulation. Since the RT pin of U1 is floating, the

SYNC pin is an output. This synchronization signal is fed to the SYNC pin of U2. The RT pin of U2 has a 110-kΩ resistor to ground, and the SYNC pin for this device acts as an input. The 1.8-V supply operates synchronously with the 3.3-V supply and their switching node rising edges are approximately 180° out of phase allowing for a reduction in the input voltage ripple. See Figure 19 for this wave form.

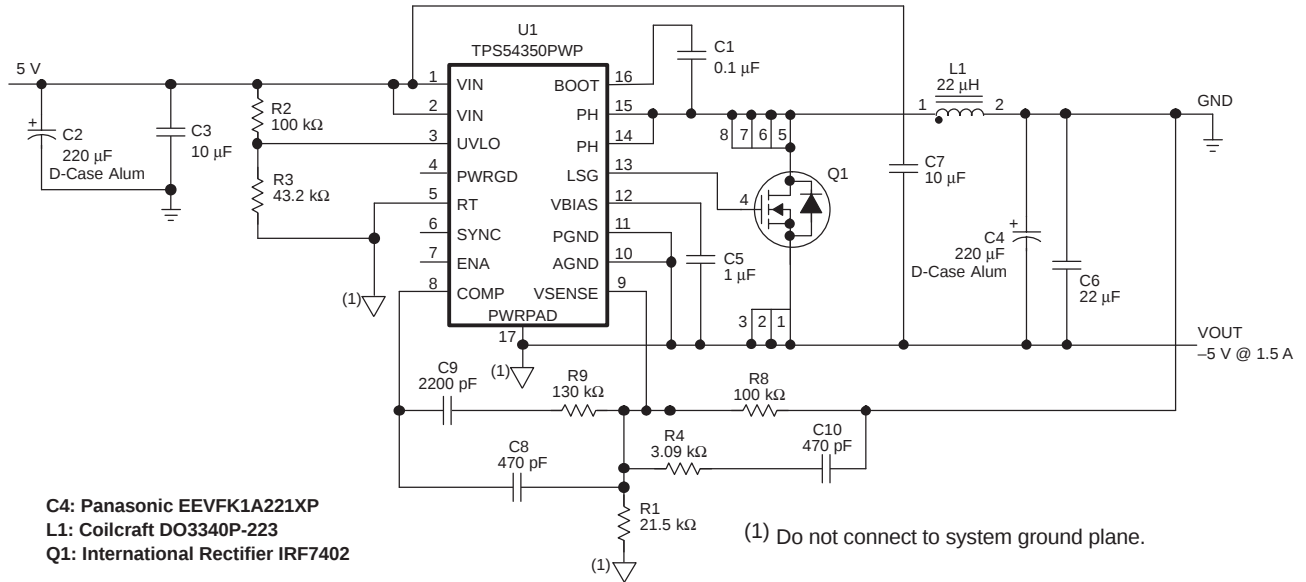


Figure 27. Inverting Power Supply, 5 V to -5 V at 1.5 A

In Figure 27 the TPS54350 is configured as an inverting supply. The -5-V output is at the pins which would normally be connected to ground. The output junction of the LC

output filter, which is normally the output in a buck converter, is tied to ground. An additional 10-μF capacitor, C7, is required from the output to VIN.

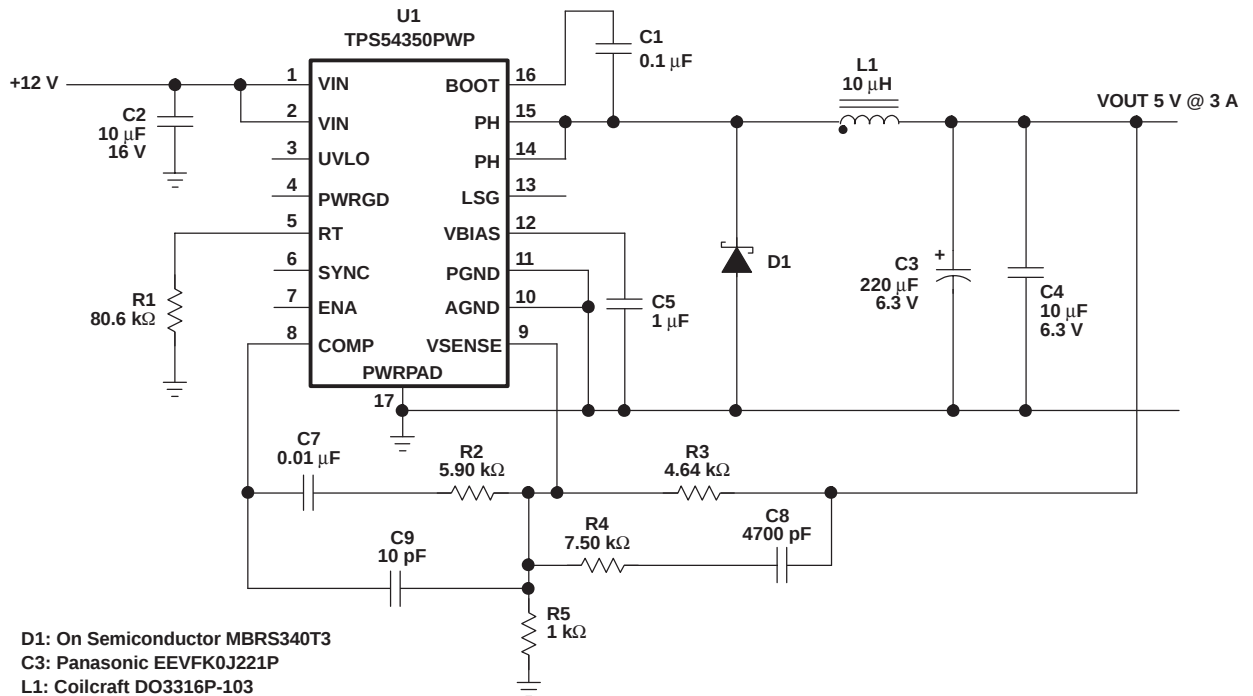


Figure 28. 12-V to 5-V Using Aluminum Electrolytic for LCD TV

Figure 28 is an example of a 12-V to 5-V converter using economical output filter components.

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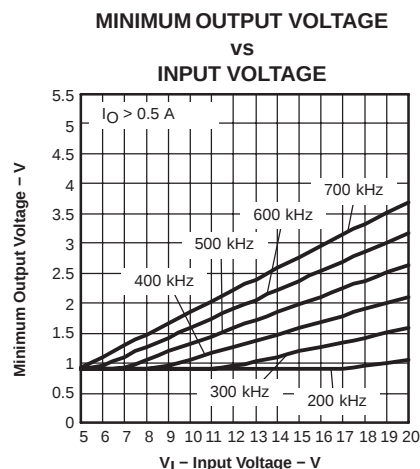


Figure 29

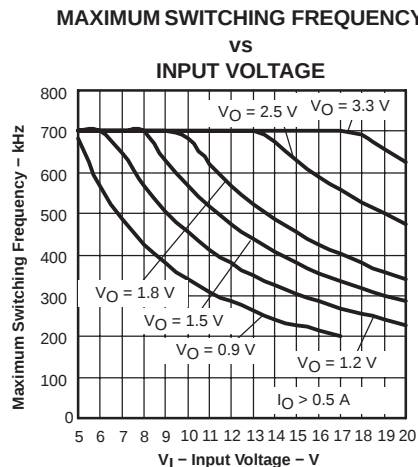


Figure 30

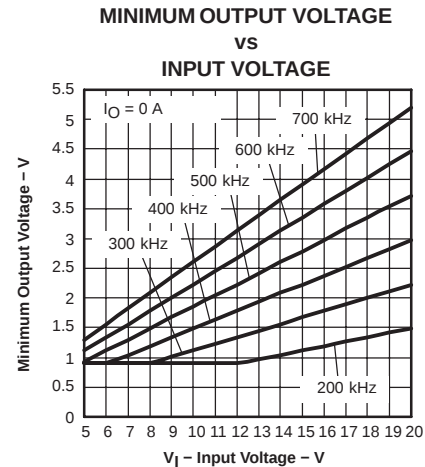


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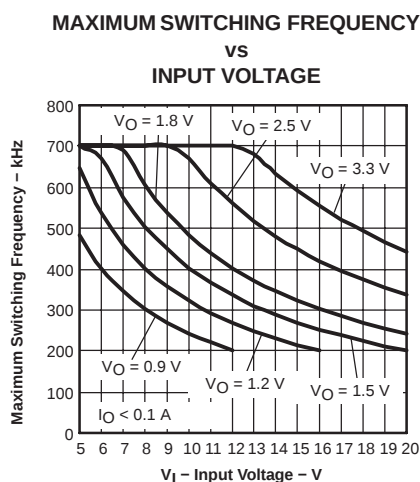


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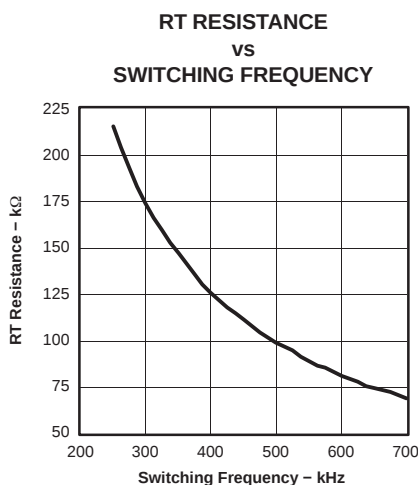


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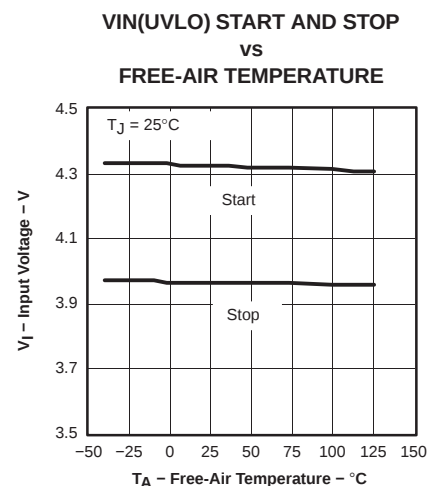


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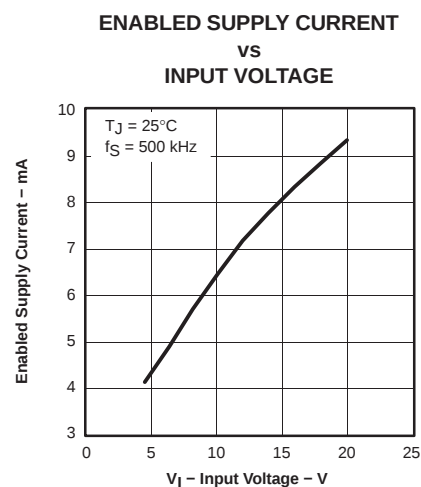


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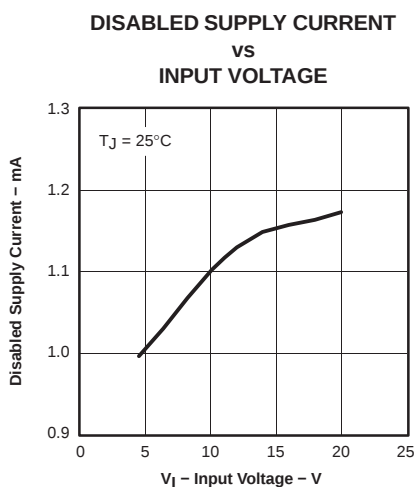


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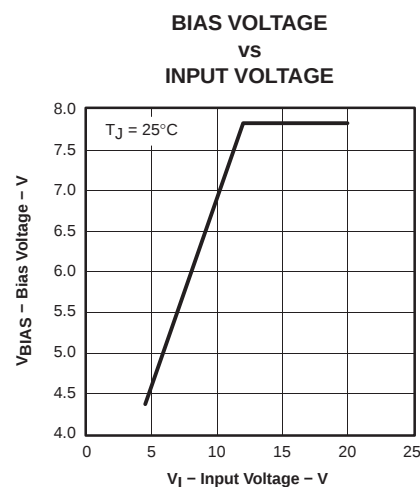


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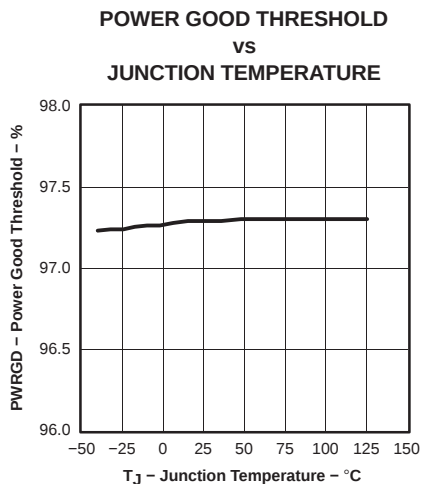


Figure 38

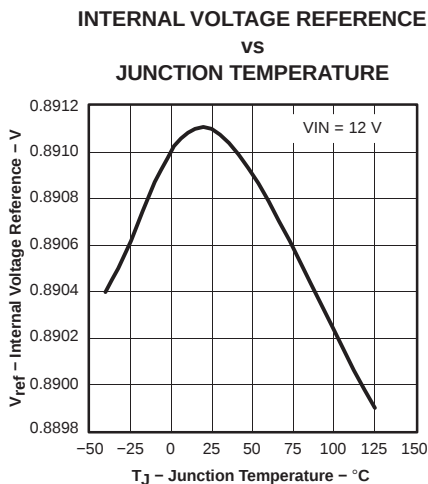


Figure 39

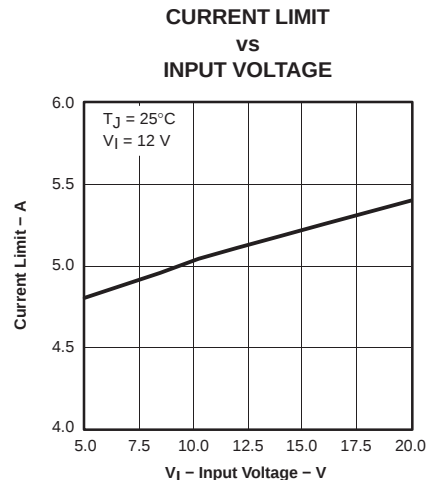


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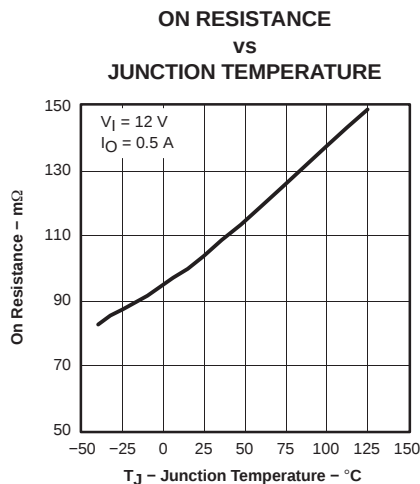


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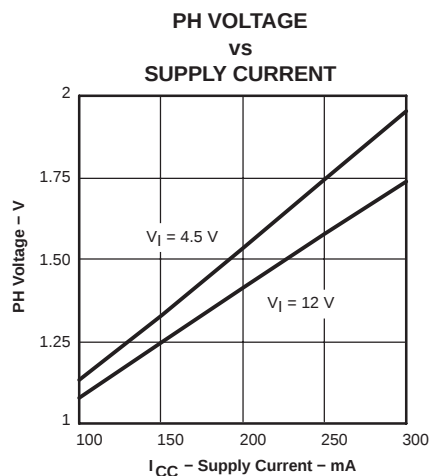


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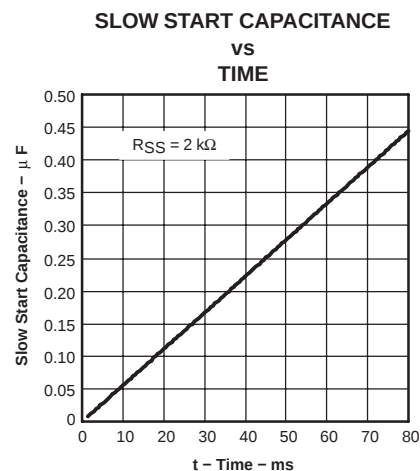


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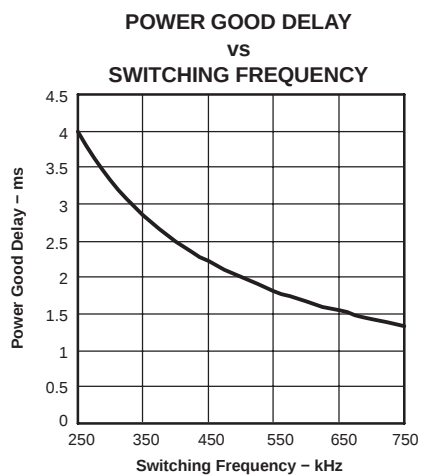


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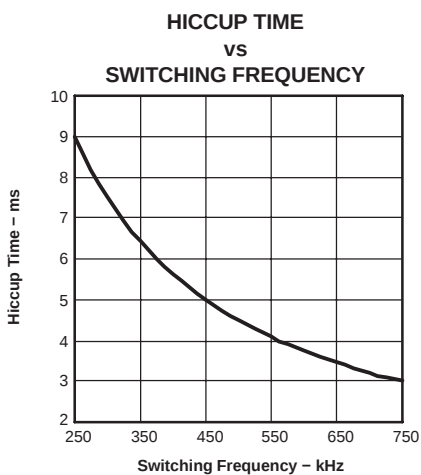


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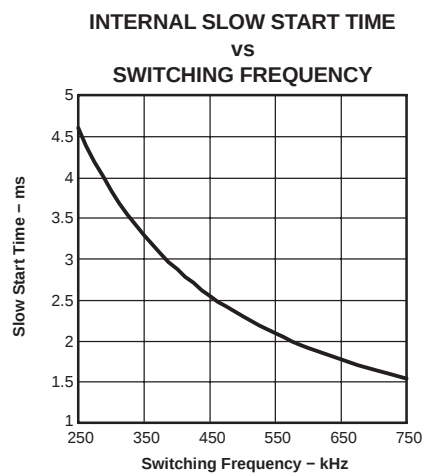


Figure 46

TPS54350

SLVS456C – OCTOBER 2003 – REVISED OCTOBER 2004

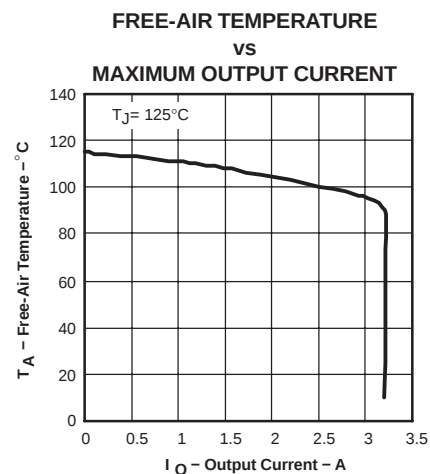


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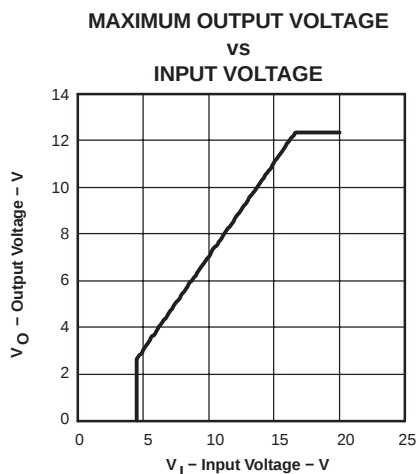


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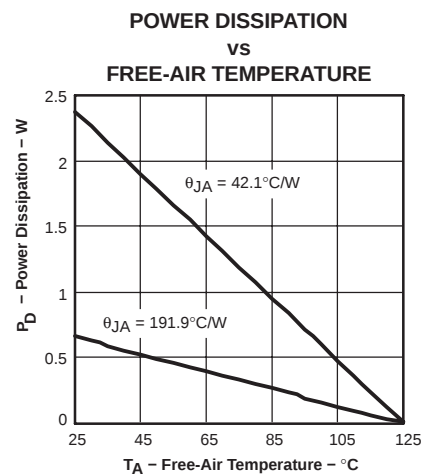
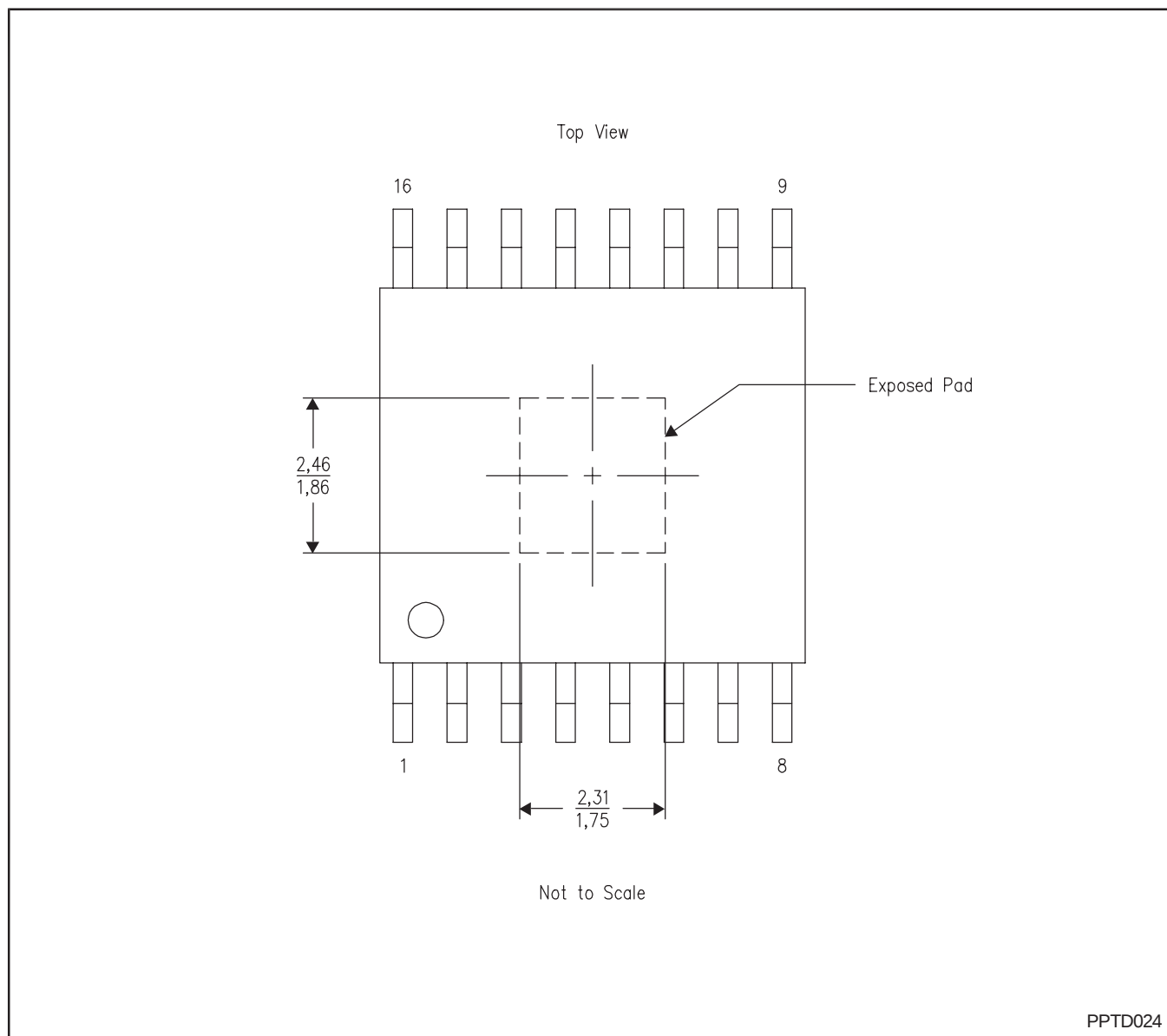


Figure 49

THERMAL PAD MECHANICAL DATA

PWP (R-PDSO-G16)

PowerPAD™ PLASTIC SMALL-OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. For additional information on the PowerPAD™ package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, **PowerPAD Thermally Enhanced Package**, Texas Instruments Literature No. SLMA002 and Application Brief, **PowerPAD Made Easy**, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS54350PWP	Active	Production	HTSSOP (PWP) 16	90 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	PS54350
TPS54350PWP.A	Active	Production	HTSSOP (PWP) 16	90 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	PS54350
TPS54350PWPG4	Active	Production	HTSSOP (PWP) 16	90 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	PS54350
TPS54350PWPR	Active	Production	HTSSOP (PWP) 16	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	PS54350
TPS54350PWPR.A	Active	Production	HTSSOP (PWP) 16	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	PS54350
TPS54350PWPRG4	Active	Production	HTSSOP (PWP) 16	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	PS54350

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS54350 :

- Enhanced Product : [TPS54350-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS54350PWPR	HTSSOP	PWP	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



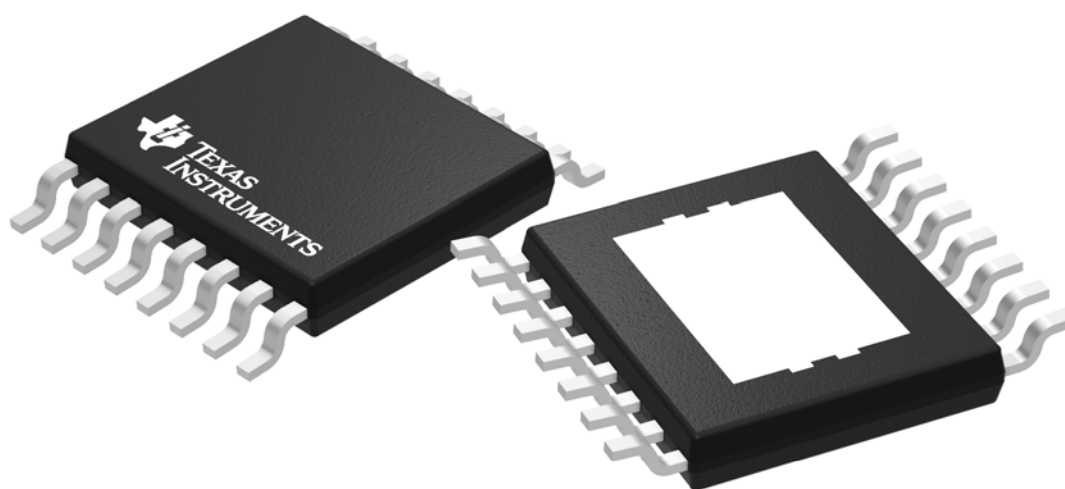
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS54350PWPR	HTSSOP	PWP	16	2000	353.0	353.0	32.0

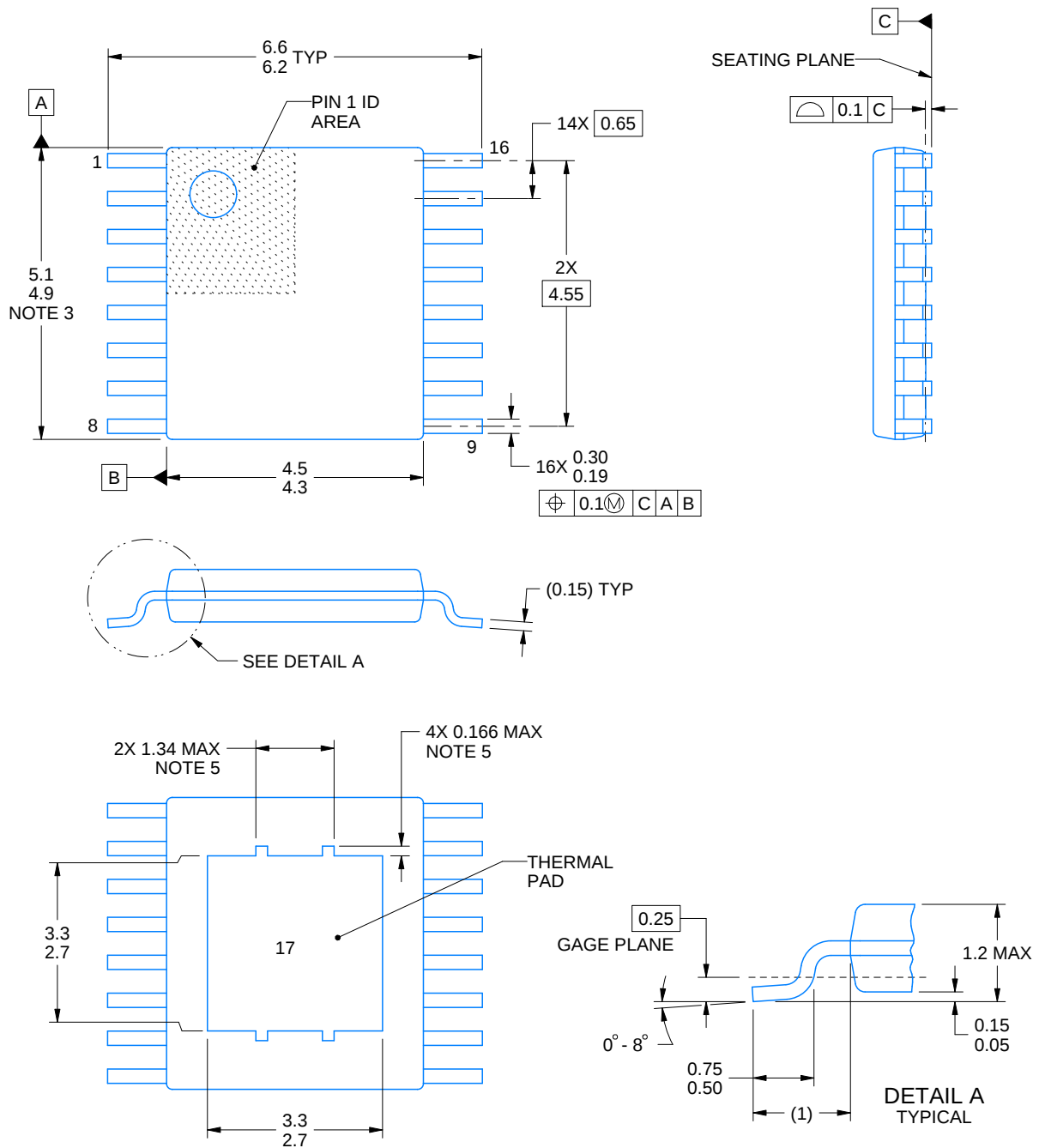
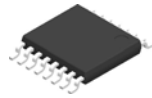
TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TPS54350PWP	PWP	HTSSOP	16	90	530	10.2	3600	3.5
TPS54350PWP	PWP	HTSSOP	16	90	530	10.2	3600	3.5
TPS54350PWP.A	PWP	HTSSOP	16	90	530	10.2	3600	3.5
TPS54350PWP.A	PWP	HTSSOP	16	90	530	10.2	3600	3.5
TPS54350PWPG4	PWP	HTSSOP	16	90	530	10.2	3600	3.5
TPS54350PWPG4	PWP	HTSSOP	16	90	530	10.2	3600	3.5



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4214868/A 02/2017

NOTES:

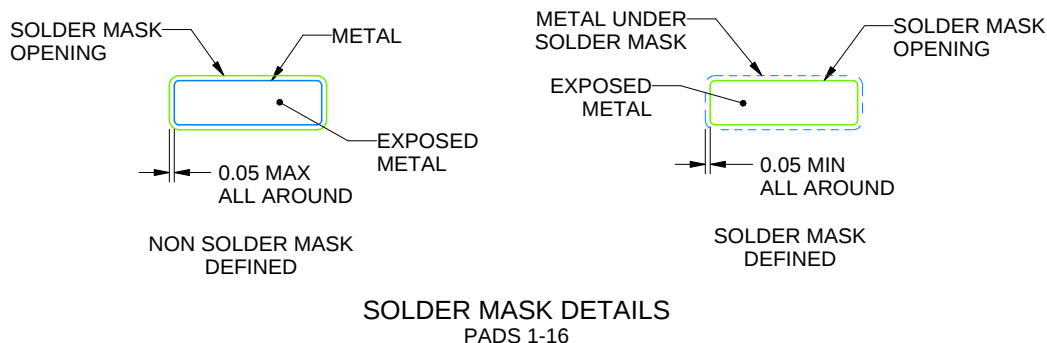
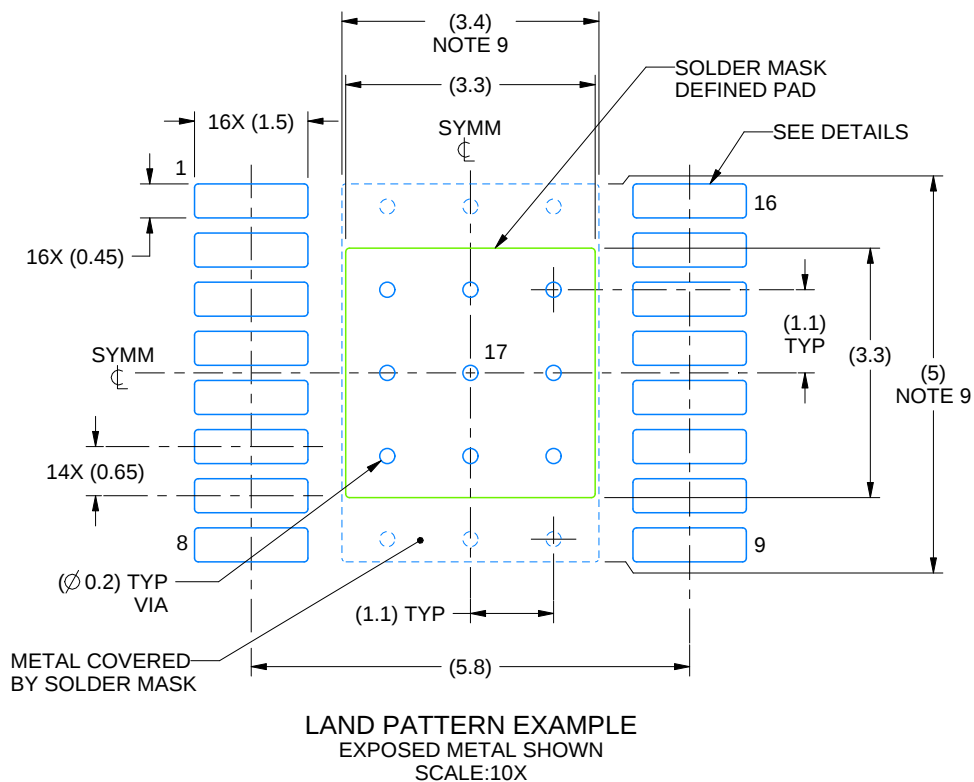
PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.
5. Features may not be present.

PWP0016A

PowerPAD™ HTSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



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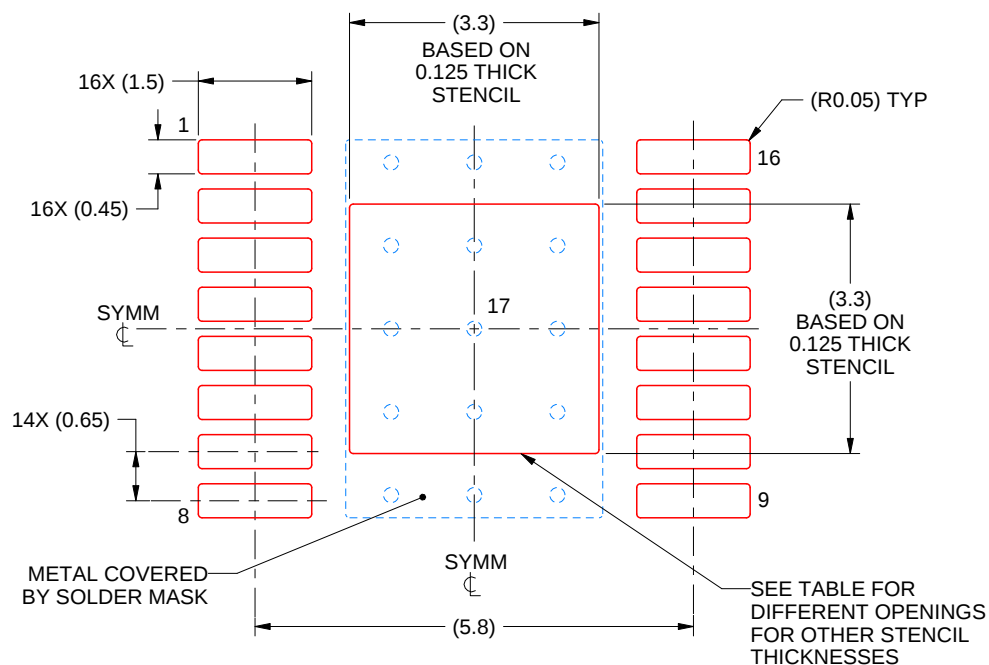
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.

PWP0016A

PowerPAD™ HTSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:10X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.69 X 3.69
0.125	3.3 X 3.3 (SHOWN)
0.15	3.01 X 3.01
0.175	2.79 X 2.79

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NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

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